

LM7321x Single and LM7322x Dual Rail-to-Rail Input and Output ± 15 -V, High-Output Current and Unlimited Capacitive Load Operational Amplifier

1 Features

- ($V_S = \pm 15$, $T_A = 25^\circ\text{C}$, Typical Values Unless Specified.)
- Wide Supply Voltage Range 2.5 V to 32 V
- Output Current +65 mA/–100 mA
- Gain Bandwidth Product 20 MHz
- Slew Rate 18 V/ μs
- Capacitive Load Tolerance Unlimited
- Input Common-Mode Voltage 0.3-V Beyond Rails
- Input Voltage Noise 15 nV/ $\sqrt{\text{Hz}}$
- Input Current Noise 1.3 pA/ $\sqrt{\text{Hz}}$
- Supply Current/Channel 1.1 mA
- Distortion THD+Noise –86 dB
- Temperature Range -40°C to 125°C
- Tested at -40°C , 25°C and 125°C at 2.7 V, ± 5 V, ± 15 V.
- LM732xx are Automotive Grade Products that are AEC-Q100 Grade 1 Qualified.

2 Applications

- Driving MOSFETs and Power Transistors
- Capacitive Proximity Sensors
- Driving Analog Optocouplers
- High-Side Sensing
- Below Ground Current Sensing
- Photodiode Biasing
- Driving Varactor Diodes in PLLs
- Wide Voltage Range Power supplies
- Automotive
- International Power Supplies

3 Description

The LM732xx devices are rail-to-rail input and output amplifiers with wide operating voltages and high-output currents. The LM732xx family is efficient, achieving 18-V/ μs slew rate and 20-MHz unity gain bandwidth while requiring only 1 mA of supply current per op amp. The LM732xx device performance is fully specified for operation at 2.7 V, ± 5 V and ± 15 V.

The LM732xx devices are designed to drive unlimited capacitive loads without oscillations. All LM7321x and LM7322x parts are tested at -40°C , 125°C , and 25°C , with modern automatic test equipment. High performance from -40°C to 125°C , detailed specifications, and extensive testing makes them suitable for industrial, automotive, and communications applications.

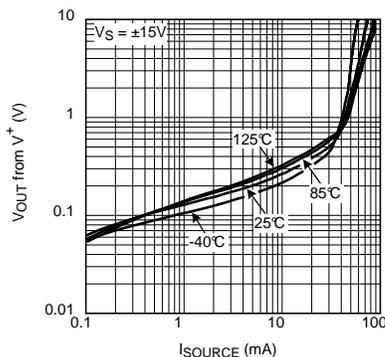
Greater than rail-to-rail input common-mode voltage range with 50 dB of common-mode rejection across this wide voltage range, allows both high-side and low-side sensing. Most device parameters are insensitive to power supply voltage, and this makes the parts easier to use where supply voltage may vary, such as automotive electrical systems and battery powered equipment. These amplifiers have true rail-to-rail output and can supply a respectable amount of current (15 mA) with minimal head-room from either rail (300 mV) at low distortion (0.05% THD+Noise).

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM7321	SOIC (8)	4.90 mm x 3.91 mm
LM7322	SOT (5)	2.90 mm x 1.60 mm
LM7322	VSSOP (8)	3.00 mm x 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Output Swing vs. Sourcing Current



Large Signal Step Response

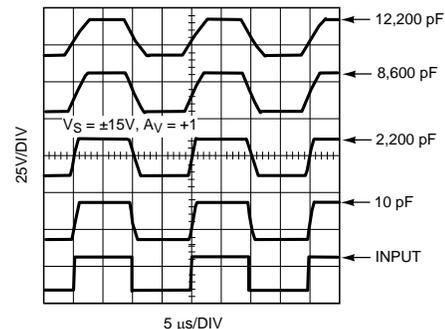


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

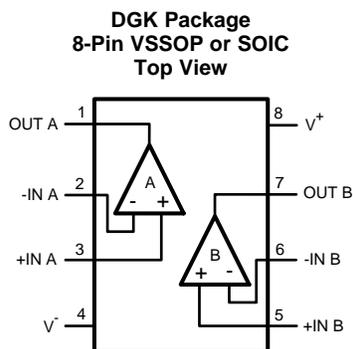
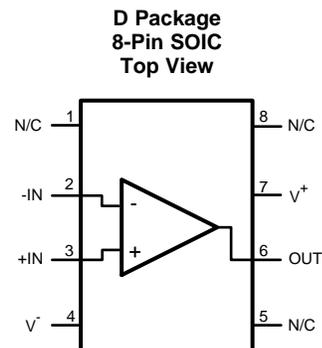
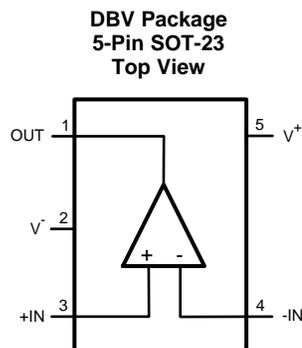
Changes from Revision D (March 2013) to Revision E	Page
<ul style="list-style-type: none"> Added <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i>, <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section 	1

Changes from Revision C (May 2008) to Revision D	Page
<ul style="list-style-type: none"> Changed layout of National Data Sheet to TI format 	25

5 Description continued

There are several package options for each part. Standard SOIC versions of both parts make upgrading existing designs easy. LM7322x are offered in a space-saving 8-Pin VSSOP package. The LM7321x are offered in small SOT-23 package, which makes it easy to place this part close to sensors for better circuit performance.

6 Pin Configuration and Functions



Pin Functions

NAME	PIN			I/O	DESCRIPTION
	SOT-23 NO.	SOIC NO.	VSSOP, SOIC NO.		
OUT	1	6	—	O	Output
OUT A	—	—	1	O	Output for Amplifier A
OUT B	—	—	7	O	Output for Amplifier B
V+	5	7	7	P	Positive Supply
V-	2	4	4	P	Negative Supply
+IN	3	3	—	I	Noninverting Input
-IN	4	2	—	I	Inverting Input
+IN A	—	—	3	I	Noninverting Input for Amplifier A
-IN A	—	—	2	I	Inverting Input for Amplifier A
+IN B	—	—	5	I	Noninverting Input for Amplifier B
-IN B	—	—	6	I	Inverting Input for Amplifier B
N/C	—	1, 5, 8	—	—	No connection

7 Specifications

7.1 Absolute Maximum Ratings

 over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

		MIN	MAX	UNIT
V _{IN} Differential			±10	V
Output Short Circuit Current		See ⁽³⁾		
Supply Voltage (V _S = V ⁺ - V ⁻)			35	V
Voltage at Input/Output pins		V ⁺ + 0.8	V ⁻ - 0.8	V
Junction Temperature ⁽⁴⁾			150	°C
Soldering Information:	Infrared or Convection (20 sec.)		235	°C
	Wave Soldering (10 sec.)		260	°C
Storage Temperature		-65	150	°C

- Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Short circuit test is a momentary test. Output short circuit duration is infinite for V_S ≤ 6V at room temperature and below. For V_S > 6V, allowable short circuit duration is 1.5 ms.
- The maximum power dissipation is a function of T_{J(MAX)}, R_{θJA}. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A) / R_{θJA}. All numbers apply for packages soldered directly onto a PCB.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge ⁽¹⁾	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽²⁾	±2000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽³⁾	±1000	
	Machine Model	200	

- Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).
- JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	MAX	UNIT
Supply Voltage (V _S = V ⁺ - V ⁻)		2.5	32	V
Temperature Range ⁽¹⁾		-40	125	°C

- The maximum power dissipation is a function of T_{J(MAX)}, R_{θJA}. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A) / R_{θJA}. All numbers apply for packages soldered directly onto a PCB.

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾	LM7321			UNIT
	D (SOIC)	DBV (SOT)	DGK (VSSOP)	
	8 PINS	5 PINS	8 PINS	
R _{θJA} ⁽²⁾ Junction-to-ambient thermal resistance	165	325	235	°C/W

- For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).
- The maximum power dissipation is a function of T_{J(MAX)}, R_{θJA}. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A) / R_{θJA}. All numbers apply for packages soldered directly onto a PCB.

7.5 2.7-V Electrical Characteristics

Unless otherwise specified, all limits ensured for $T_A = 25^\circ\text{C}$, $V^+ = 2.7\text{ V}$, $V^- = 0\text{ V}$, $V_{\text{CM}} = 0.5\text{ V}$, $V_{\text{OUT}} = 1.35\text{ V}$, and $R_L > 1\text{ M}\Omega$ to 1.35 V .⁽¹⁾

PARAMETER		TEST CONDITION	MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT	
V_{OS}	Input Offset Voltage	$V_{\text{CM}} = 0.5\text{ V}$ and $V_{\text{CM}} = 2.2\text{ V}$		-5	± 0.7	+5	mV
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	-6		+6	
$\text{TC } V_{\text{OS}}$	Input Offset Voltage Temperature Drift	$V_{\text{CM}} = 0.5\text{ V}$ and $V_{\text{CM}} = 2.2\text{ V}$ ⁽⁴⁾		± 2		$\mu\text{V}/^\circ\text{C}$	
I_{B}	Input Bias Current	$V_{\text{CM}} = 0.5\text{ V}$ ⁽⁵⁾		-2	-1.2	μA	
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	-2.5			
I_{OS}	Input Offset Current	$V_{\text{CM}} = 0.5\text{ V}$ and $V_{\text{CM}} = 2.2\text{ V}$			0.45	1	nA
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$			1.5	
CMRR	Common-Mode Rejection Ratio	$0\text{ V} \leq V_{\text{CM}} \leq 1\text{ V}$		70	100	dB	
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	60			
PSRR	Power Supply Rejection Ratio	$2.7\text{ V} \leq V_{\text{S}} \leq 30\text{ V}$		78	104	dB	
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	74			
CMVR	Common-Mode Voltage Range (Min)	CMRR > 50 dB		-0.3	-0.1	V	
	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$				0		
	Common-Mode Voltage Range (Max)	CMRR > 50 dB		2.8	3		
	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$			2.7			
A_{VOL}	Open-Loop Voltage Gain	$0.5\text{ V} \leq V_{\text{O}} \leq 2.2\text{ V}$ $R_L = 10\text{ k}\Omega$ to 1.35 V		65	72	dB	
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	62			
		$0.5\text{ V} \leq V_{\text{O}} \leq 2.2\text{ V}$ $R_L = 2\text{ k}\Omega$ to 1.35 V		59	66		
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	55			
V_{OUT}	Output Voltage Swing High	$R_L = 10\text{ k}\Omega$ to 1.35 V $V_{\text{ID}} = 100\text{ mV}$			50	150	mV from either rail
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$				
	Output Voltage Swing Low	$R_L = 2\text{ k}\Omega$ to 1.35 V $V_{\text{ID}} = 100\text{ mV}$			100	250	
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$				
		$R_L = 10\text{ k}\Omega$ to 1.35 V $V_{\text{ID}} = -100\text{ mV}$		20	120		
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$				
		$R_L = 2\text{ k}\Omega$ to 1.35 V $V_{\text{ID}} = -100\text{ mV}$		40	120		
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$				
I_{OUT}	Output Current	Sourcing $V_{\text{ID}} = 200\text{ mV}$, $V_{\text{OUT}} = 0\text{ V}$ ⁽⁶⁾		30	48	mA	
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		20		
			Sinking $V_{\text{ID}} = -200\text{ mV}$, $V_{\text{OUT}} = 2.7\text{ V}$ ⁽⁶⁾		40		65
$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		30					

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.
- (2) All limits are ensured by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- (4) Offset voltage temperature drift determined by dividing the change in V_{OS} at temperature extremes into the total temperature change.
- (5) Positive current corresponds to current flowing into the device.
- (6) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C . Short circuit test is a momentary test. Output short circuit duration is infinite for $V_{\text{S}} \leq 6\text{ V}$ at room temperature and below. For $V_{\text{S}} > 6\text{ V}$, allowable short circuit duration is 1.5 ms.

2.7-V Electrical Characteristics (continued)

Unless otherwise specified, all limits ensured for $T_A = 25^\circ\text{C}$, $V^+ = 2.7\text{ V}$, $V^- = 0\text{ V}$, $V_{\text{CM}} = 0.5\text{ V}$, $V_{\text{OUT}} = 1.35\text{ V}$, and $R_L > 1\text{ M}\Omega$ to 1.35 V .⁽¹⁾

PARAMETER		TEST CONDITION	MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT
I_S	Supply Current	LM7321		0.95	1.3	mA
			$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		1.9	
		LM7322		2	2.5	
			$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		3.8	
SR	Slew Rate ⁽⁷⁾	$A_V = +1$, $V_I = 2\text{-V Step}$		8.5		V/ μs
f_u	Unity Gain Frequency	$R_L = 2\text{ k}\Omega$, $C_L = 20\text{ pF}$		7.5		MHz
GBW	Gain Bandwidth	$f = 50\text{ kHz}$		16		MHz
e_n	Input Referred Voltage Noise Density	$f = 2\text{ kHz}$		11.9		nV/ $\sqrt{\text{Hz}}$
i_n	Input Referred Current Noise Density	$f = 2\text{ kHz}$		0.5		pA/ $\sqrt{\text{Hz}}$
THD+N	Total Harmonic Distortion + Noise	$V^+ = 1.9\text{ V}$, $V^- = -0.8\text{ V}$ $f = 1\text{ kHz}$, $R_L = 100\text{ k}\Omega$, $A_V = +2$ $V_{\text{OUT}} = 210\text{ mV}_{\text{PP}}$		-77		dB
CT Rej.	Crosstalk Rejection	$f = 100\text{ kHz}$, Driver $R_L = 10\text{ k}\Omega$		60		dB

(7) Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.

7.6 ±5-V Electrical Characteristics

Unless otherwise specified, all limited ensured for $T_A = 25^\circ\text{C}$, $V^+ = 5\text{ V}$, $V^- = -5\text{ V}$, $V_{\text{CM}} = 0\text{ V}$, $V_{\text{OUT}} = 0\text{ V}$, and $R_L > 1\text{ M}\Omega$ to 0 V.⁽¹⁾

PARAMETER		TEST CONDITION	MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT	
V_{OS}	Input Offset Voltage	$V_{\text{CM}} = -4.5\text{ V}$ and $V_{\text{CM}} = 4.5\text{ V}$	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	-5	±0.7	+5	mV
				-6		+6	
TC V_{OS}	Input Offset Voltage Temperature Drift	$V_{\text{CM}} = -4.5\text{ V}$ and $V_{\text{CM}} = 4.5\text{ V}$ ⁽⁴⁾		±2		µV/°C	
I_{B}	Input Bias Current	$V_{\text{CM}} = -4.5\text{ V}$ ⁽⁵⁾	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	-2.0	-1.2		µA
				-2.5			
I_{OS}	Input Offset Current	$V_{\text{CM}} = -4.5\text{ V}$ and $V_{\text{CM}} = 4.5\text{ V}$	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		0.45	1	nA
					20	200	
CMRR	Common Mode Rejection Ratio	$-5\text{ V} \leq V_{\text{CM}} \leq 3\text{ V}$	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	80	100		dB
				70			
PSRR	Power Supply Rejection Ratio	$2.7\text{ V} \leq V_{\text{S}} \leq 30\text{ V}$, $V_{\text{CM}} = -4.5\text{ V}$	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	78	104		dB
				74			
CMVR	Common-Mode Voltage Range (Min)	CMRR > 50 dB	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		-5.3	-5.1	V
	Common-Mode Voltage Range (Max)			5.1	5.3		
A_{VOL}	Open-Loop Voltage Gain	$-4\text{ V} \leq V_{\text{O}} \leq 4\text{ V}$ $R_L = 10\text{ k}\Omega$ to 0 V	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	74	80		dB
				70			
V_{OUT}	Output Voltage Swing High	$R_L = 10\text{ k}\Omega$ to 0 V $V_{\text{ID}} = 100\text{ mV}$	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		100	250	mV from either rail
						280	
	Output Voltage Swing Low	$R_L = 2\text{ k}\Omega$ to 0 V $V_{\text{ID}} = 100\text{ mV}$	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		160	350	
						450	
I_{OUT}	Output Current	Sourcing $V_{\text{ID}} = 200\text{ mV}$, $V_{\text{OUT}} = -5\text{ V}$ ⁽⁶⁾	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	35	70		mA
				20			
I_{OUT}	Output Current	Sinking $V_{\text{ID}} = -200\text{ mV}$, $V_{\text{OUT}} = 5\text{ V}$ ⁽⁶⁾	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	50	85		
				30			

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.
- (2) All limits are ensured by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.
- (4) Offset voltage temperature drift determined by dividing the change in V_{OS} at temperature extremes into the total temperature change.
- (5) Positive current corresponds to current flowing into the device.
- (6) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C . Short circuit test is a momentary test. Output short circuit duration is infinite for $V_{\text{S}} \leq 6\text{ V}$ at room temperature and below. For $V_{\text{S}} > 6\text{ V}$, allowable short circuit duration is 1.5 ms.

±5-V Electrical Characteristics (continued)

Unless otherwise specified, all limited ensured for $T_A = 25^\circ\text{C}$, $V^+ = 5\text{ V}$, $V^- = -5\text{ V}$, $V_{CM} = 0\text{ V}$, $V_{OUT} = 0\text{ V}$, and $R_L > 1\text{ M}\Omega$ to 0 V.⁽¹⁾

PARAMETER		TEST CONDITION		MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT
I_S	Supply Current	$V_{CM} = -4.5\text{ V}$	LM7321	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	1.0	1.3	mA
					2		
			LM7322	$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	2.3	2.8	
					3.8		
SR	Slew Rate ⁽⁷⁾	$A_V = +1$, $V_I = 8\text{-V}$ Step		12.3		V/ μs	
f_u	Unity Gain Frequency	$R_L = 2\text{ k}\Omega$, $C_L = 20\text{ pF}$		9		MHz	
GBW	Gain Bandwidth	$f = 50\text{ kHz}$		16		MHz	
e_n	Input Referred Voltage Noise Density	$f = 2\text{ kHz}$		14.3		nV/ $\sqrt{\text{Hz}}$	
i_n	Input Referred Current Noise Density	$f = 2\text{ kHz}$		1.35		pA/ $\sqrt{\text{Hz}}$	
THD+N	Total Harmonic Distortion + Noise	$f = 1\text{ kHz}$, $R_L = 100\text{ k}\Omega$, $A_V = +2$ $V_{OUT} = 8\text{ V}_{PP}$		-79		dB	
CT Rej.	Crosstalk Rejection	$f = 100\text{ kHz}$, Driver $R_L = 10\text{ k}\Omega$		60		dB	

(7) Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.

7.7 ±15-V Electrical Characteristics

Unless otherwise specified, all limited ensured for $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$, $V_{CM} = 0\text{ V}$, $V_{OUT} = 0\text{ V}$, and $R_L > 1\text{ M}\Omega$ to 15 V.⁽¹⁾

PARAMETER		TEST CONDITION		MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT
V_{OS}	Input Offset Voltage	$V_{CM} = -14.5\text{ V}$ and $V_{CM} = 14.5\text{ V}$		-6	± 0.7	+6	mV
			-40°C to $+125^\circ\text{C}$	-8	+8		
TC V_{OS}	Input Offset Voltage Temperature Drift	$V_{CM} = -14.5\text{ V}$ and $V_{CM} = 14.5\text{ V}$ ⁽⁴⁾			± 2		$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current	$V_{CM} = -14.5\text{ V}$ ⁽⁵⁾		-2	-1.1		μA
			-40°C to $+125^\circ\text{C}$	-2.5			
			$V_{CM} = 14.5\text{ V}$ ⁽⁵⁾		0.45	1	
I_{OS}	Input Offset Current	$V_{CM} = -14.5\text{ V}$ and $V_{CM} = 14.5\text{ V}$			30	300	nA
			-40°C to $+125^\circ\text{C}$			500	
CMRR	Common-Mode Rejection Ratio	$-15\text{ V} \leq V_{CM} \leq 12\text{ V}$		80	100		dB
			-40°C to $+125^\circ\text{C}$	75			
		$-15\text{ V} \leq V_{CM} \leq 15\text{ V}$		72	80		
			-40°C to $+125^\circ\text{C}$	70			
PSRR	Power Supply Rejection Ratio	$2.7\text{ V} \leq V_S \leq 30\text{ V}$, $V_{CM} = -14.5\text{ V}$		78	100		dB
			-40°C to $+125^\circ\text{C}$	74			

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

(2) All limits are ensured by testing or statistical analysis.

(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.

(4) Offset voltage temperature drift determined by dividing the change in V_{OS} at temperature extremes into the total temperature change.

(5) Positive current corresponds to current flowing into the device.

±15-V Electrical Characteristics (continued)

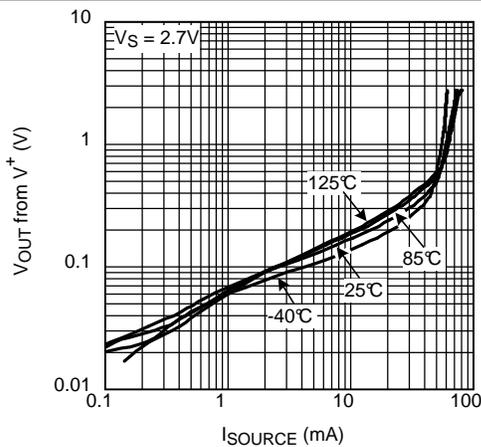
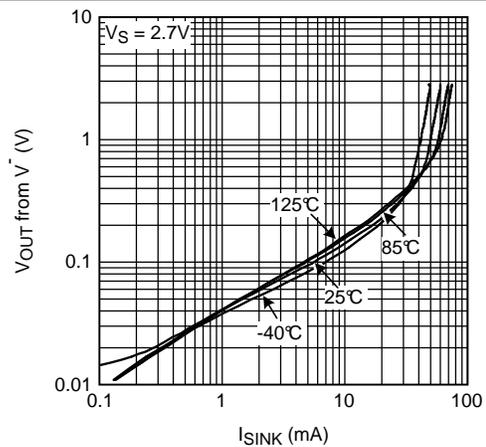
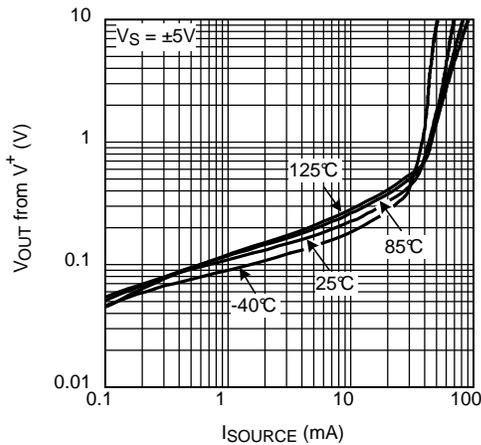
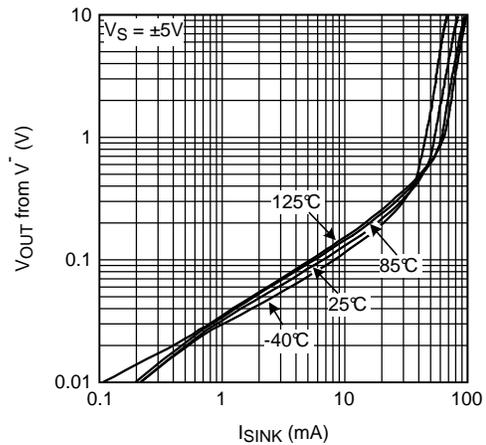
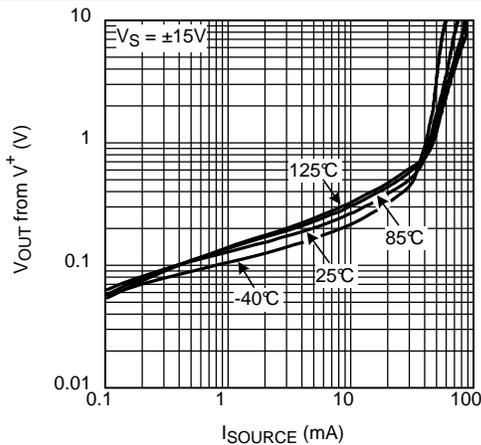
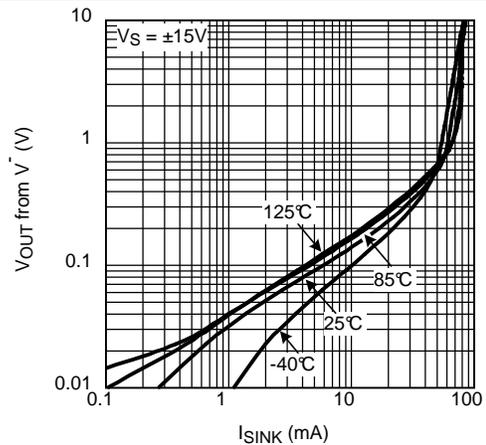
Unless otherwise specified, all limited ensured for $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$, $V_{\text{CM}} = 0\text{ V}$, $V_{\text{OUT}} = 0\text{ V}$, and $R_L > 1\text{ M}\Omega$ to 15 V .⁽¹⁾

PARAMETER		TEST CONDITION		MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT
CMVR	Common-Mode Voltage Range (Min)	CMRR > 50 dB	–40°C to +125°C		–15.3	–15.1	V
	Common-Mode Voltage Range (Max)				15.1	15.3	
A _{VOL}	Open-Loop Voltage Gain	–13 V ≤ V _O ≤ 13 V R _L = 10 kΩ to 0 V	–40°C to +125°C	75	85	dB	
			–40°C to +125°C	70			
		–13 V ≤ V _O ≤ 13 V R _L = 2 kΩ to 0 V	–40°C to +125°C	70	78		
V _{OUT}	Output Voltage Swing High	R _L = 10 kΩ to 0 V V _{ID} = 100 mV	–40°C to +125°C		150	300	mV from either rail
			–40°C to +125°C			350	
		R _L = 2 kΩ to 0 V V _{ID} = 100 mV	–40°C to +125°C		250	550	
	Output Voltage Swing Low	R _L = 10 kΩ to 0 V V _{ID} = –100 mV	–40°C to +125°C		60	200	
			–40°C to +125°C			250	
		R _L = 2 kΩ to 0 V V _{ID} = –100 mV	–40°C to +125°C		130	300	
I _{OUT}	Output Current	Sourcing V _{ID} = 200 mV, V _{OUT} = –15 V ⁽⁶⁾		40	65	mA	
		Sinking V _{ID} = –200 mV, V _{OUT} = 15 V ⁽⁶⁾		60	100		
I _S	Supply Current	V _{CM} = –14.5 V	LM7321	–40°C to +125°C	1.1	1.7	mA
				–40°C to +125°C		2.4	
			LM7322	–40°C to +125°C	2.5	4	
				–40°C to +125°C		5.6	
SR	Slew Rate ⁽⁷⁾	A _V = +1, V _I = 20-V Step			18	V/μs	
f _u	Unity Gain Frequency	R _L = 2 kΩ, C _L = 20 pF			11.3	MHz	
GBW	Gain Bandwidth	f = 50 kHz			20	MHz	
e _n	Input Referred Voltage Noise Density	f = 2 kHz			15	nV/√Hz	
i _n	Input Referred Current Noise Density	f = 2 kHz			1.3	pA/√Hz	
THD+N	Total Harmonic Distortion +Noise	f = 1 kHz, R _L 100 kΩ, A _V = +2, V _{OUT} = 23 V _{PP}			–86	dB	
CT Rej.	Crosstalk Rejection	f = 100 kHz, Driver R _L = 10 kΩ			60	dB	

(6) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Short circuit test is a momentary test. Output short circuit duration is infinite for $V_S \leq 6\text{ V}$ at room temperature and below. For $V_S > 6\text{ V}$, allowable short circuit duration is 1.5 ms.

(7) Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.

7.8 Typical Characteristics

 Unless otherwise specified: $T_A = 25^\circ\text{C}$.

Figure 1. Output Swing vs. Sourcing Current

Figure 2. Output Swing vs. Sinking Current

Figure 3. Output Swing vs. Sourcing Current

Figure 4. Output Swing vs. Sinking Current

Figure 5. Output Swing vs. Sourcing Current

Figure 6. Output Swing vs. Sinking Current

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

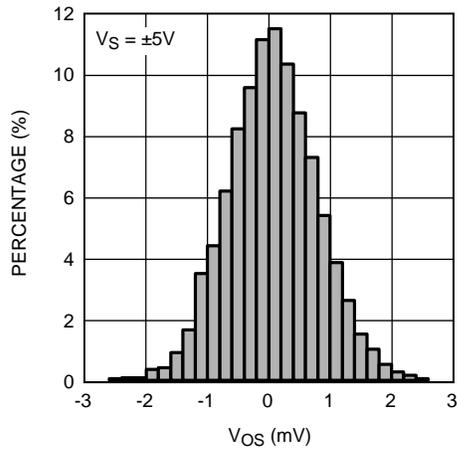


Figure 7. V_{OS} Distribution

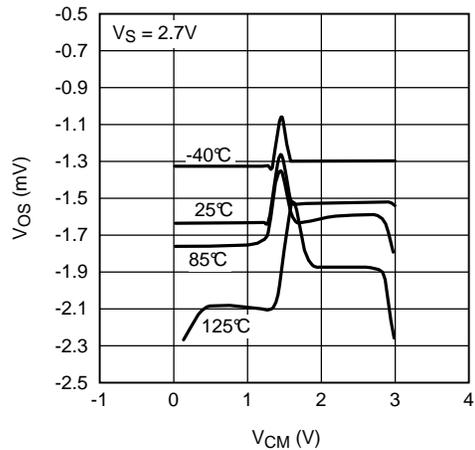


Figure 8. V_{OS} vs. V_{CM} (Unit 1)

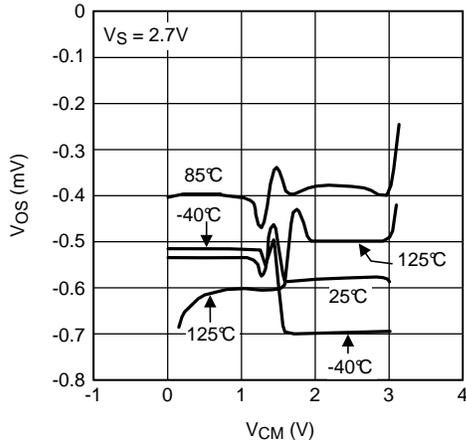


Figure 9. V_{OS} vs. V_{CM} (Unit 2)

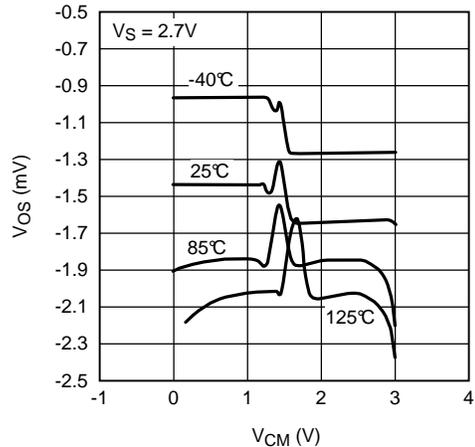


Figure 10. V_{OS} vs. V_{CM} (Unit 3)

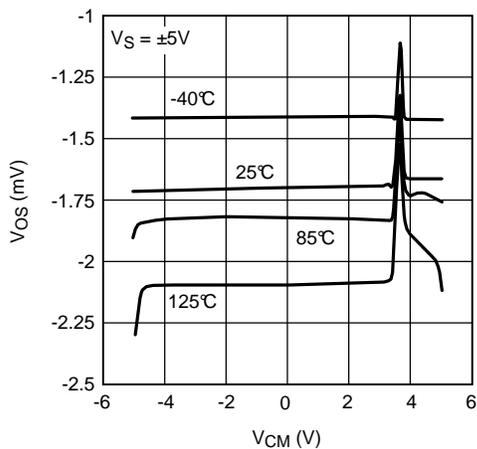


Figure 11. V_{OS} vs. V_{CM} (Unit 1)

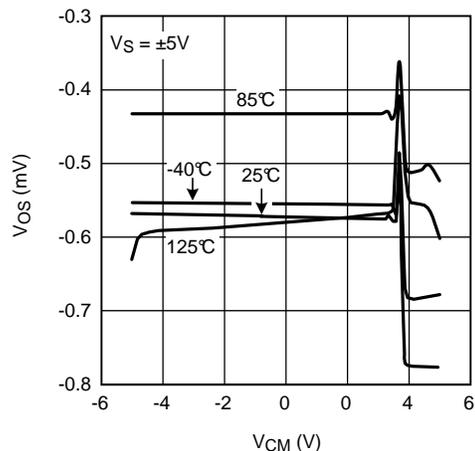


Figure 12. V_{OS} vs. V_{CM} (Unit 2)

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

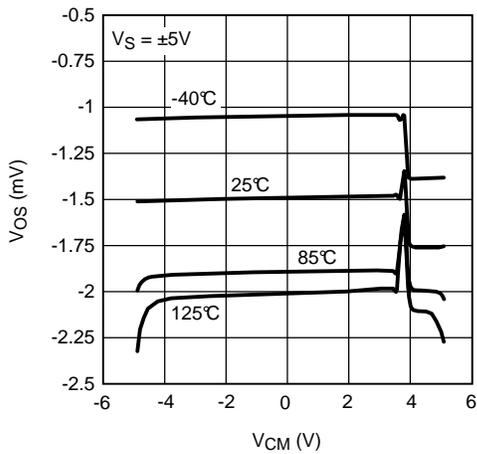


Figure 13. V_{OS} vs. V_{CM} (Unit 2)

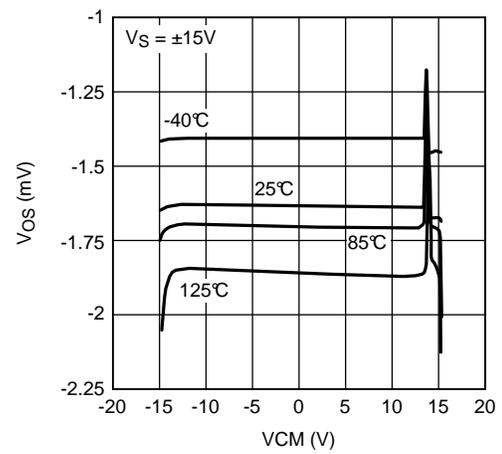


Figure 14. V_{OS} vs. V_{CM} (Unit 1)

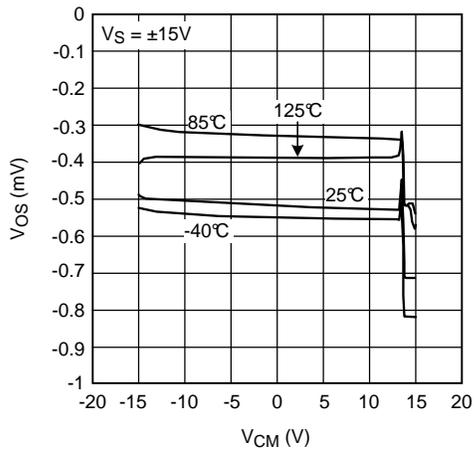


Figure 15. V_{OS} vs. V_{CM} (Unit 2)

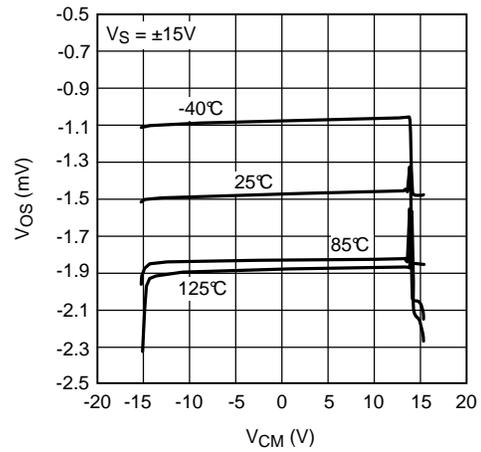


Figure 16. V_{OS} vs. V_{CM} (Unit 3)

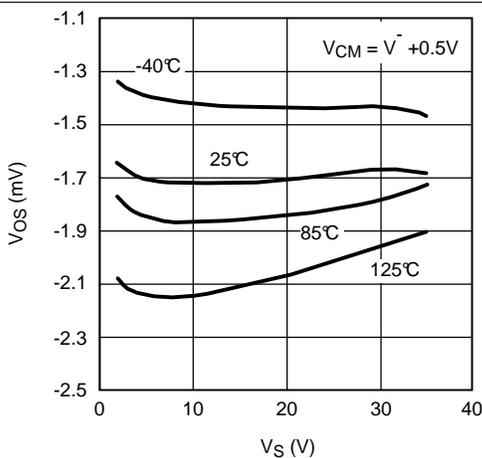


Figure 17. V_{OS} vs. V_S (Unit 1)

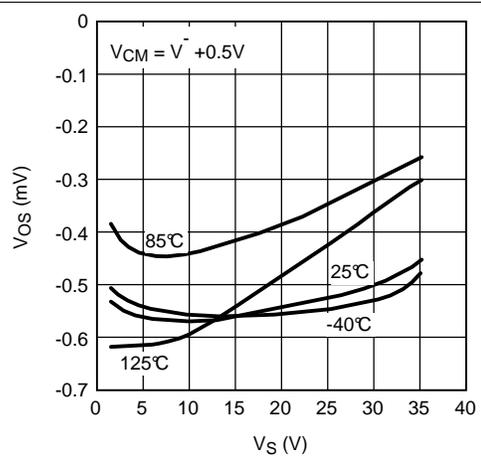


Figure 18. V_{OS} vs. V_S (Unit 2)

Typical Characteristics (continued)

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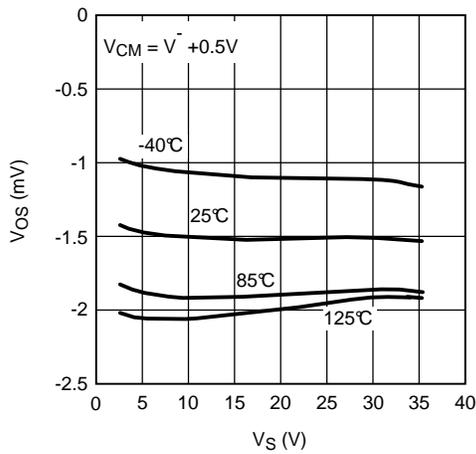


Figure 19. V_{OS} vs. V_S (Unit 3)

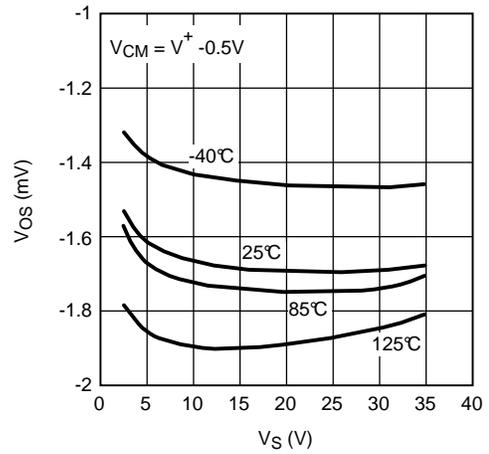


Figure 20. V_{OS} vs. V_S (Unit 1)

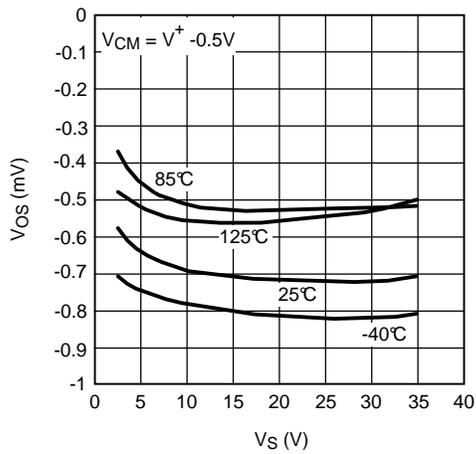


Figure 21. V_{OS} vs. V_S (Unit 2)

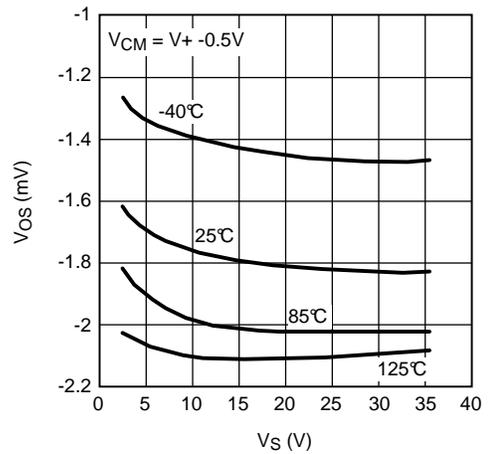


Figure 22. V_{OS} vs. V_S (Unit 3)

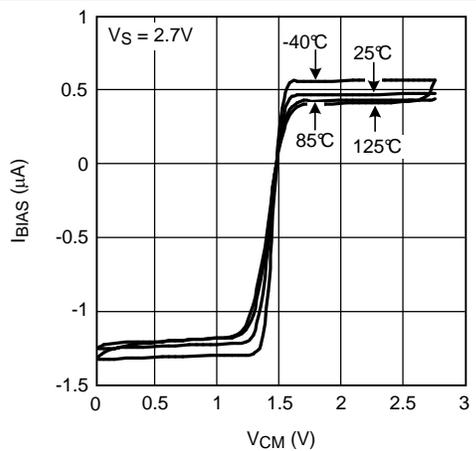


Figure 23. I_{BIAS} vs. V_{CM}

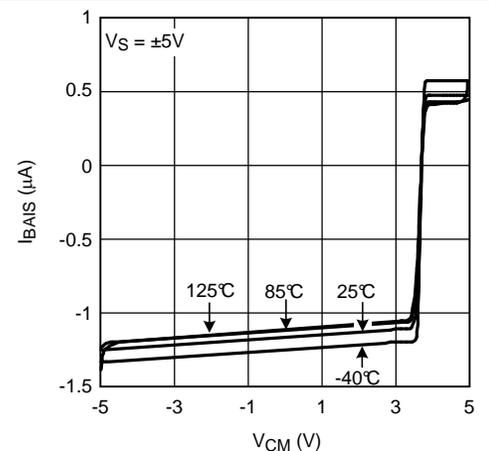


Figure 24. I_{BIAS} vs. V_{CM}

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

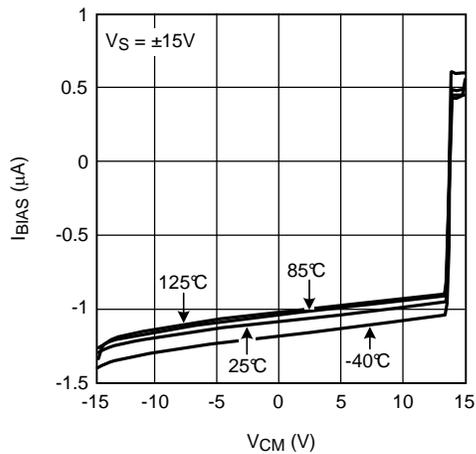


Figure 25. I_{BIAS} vs. V_{CM}

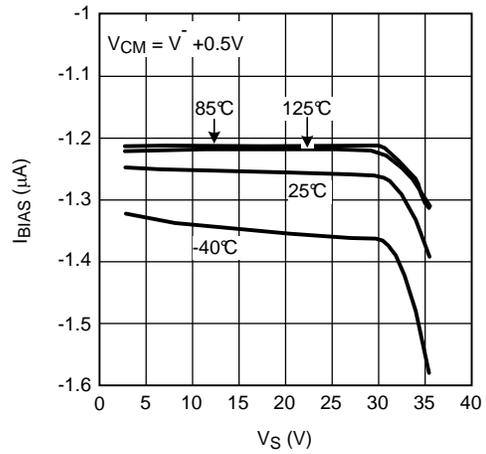


Figure 26. I_{BIAS} vs. V_S

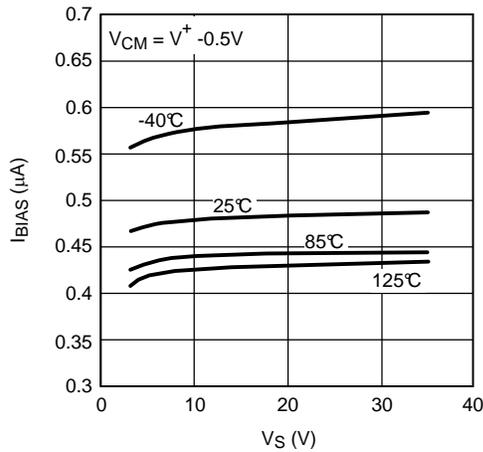


Figure 27. I_{BIAS} vs. V_S

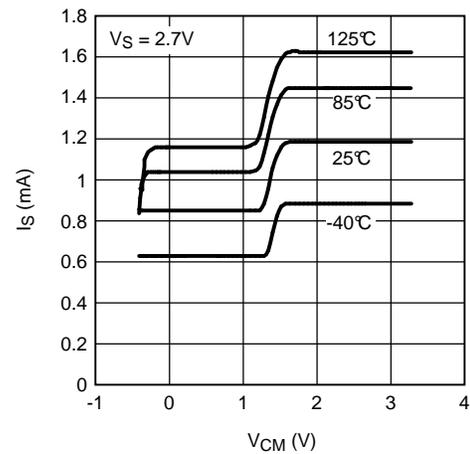


Figure 28. I_S vs. V_{CM} (LM7321)

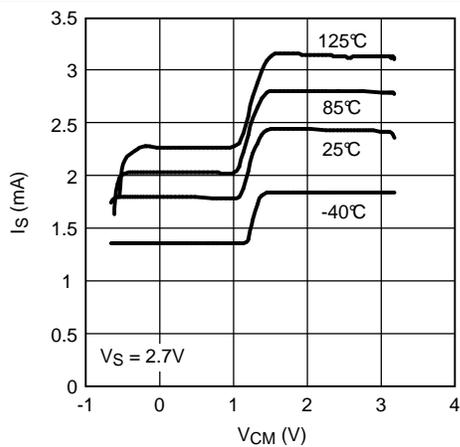


Figure 29. I_S vs. V_{CM} (LM7322)

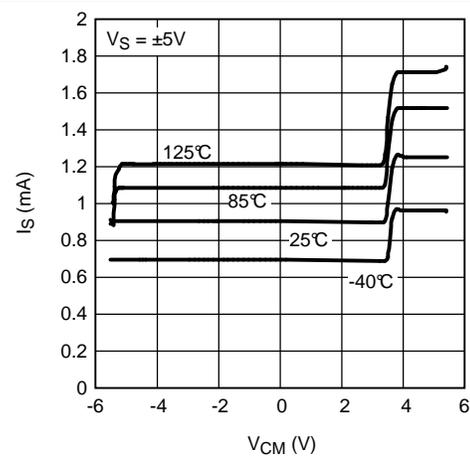


Figure 30. I_S vs. V_{CM} (LM7321)

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

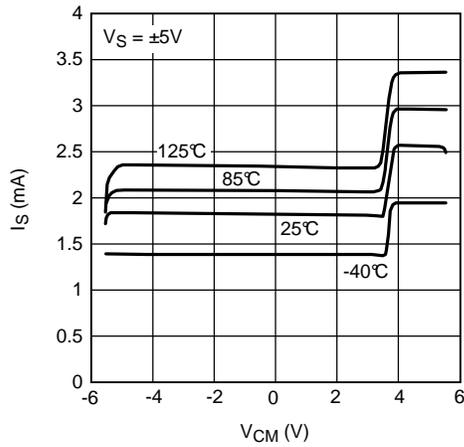


Figure 31. I_S vs. V_{CM} (LM7322)

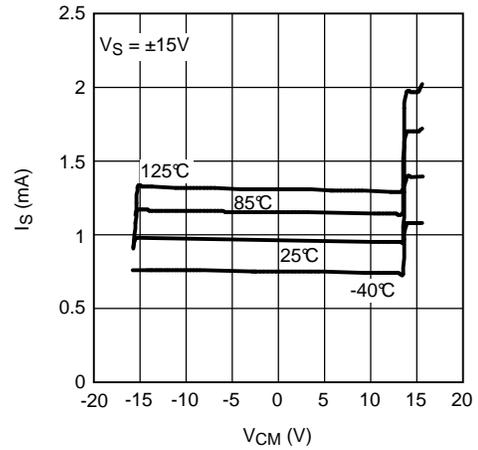


Figure 32. I_S vs. V_{CM} (LM7321)

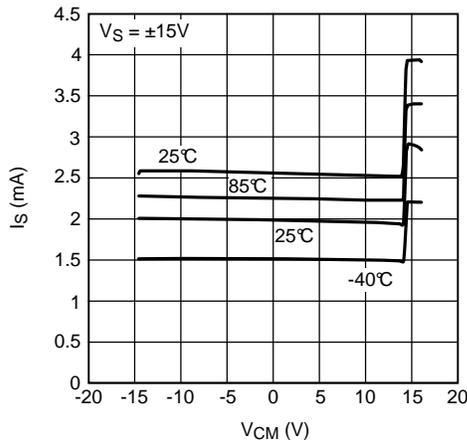


Figure 33. I_S vs. V_{CM} (LM7322)

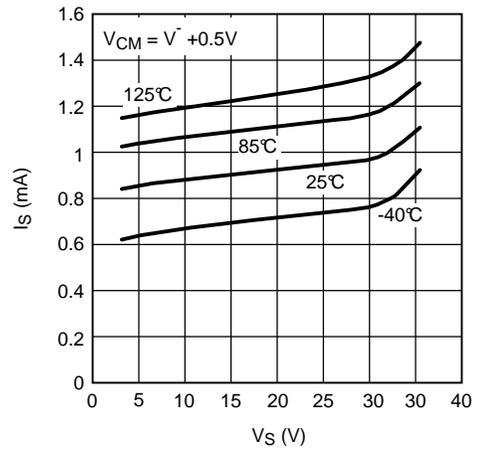


Figure 34. I_S vs. V_S (LM7321)

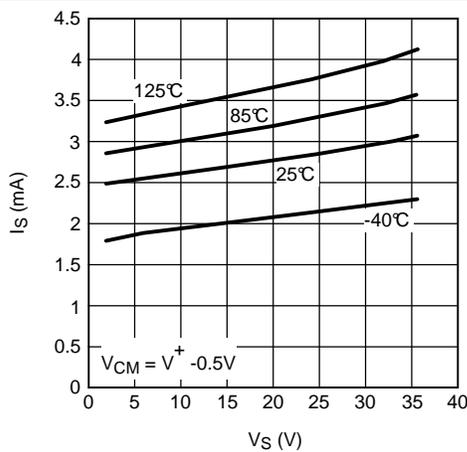


Figure 35. I_S vs. V_S (LM7322)

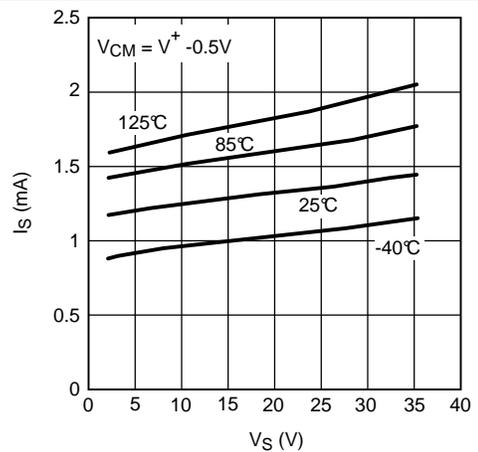


Figure 36. I_S vs. V_S (LM7321)

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

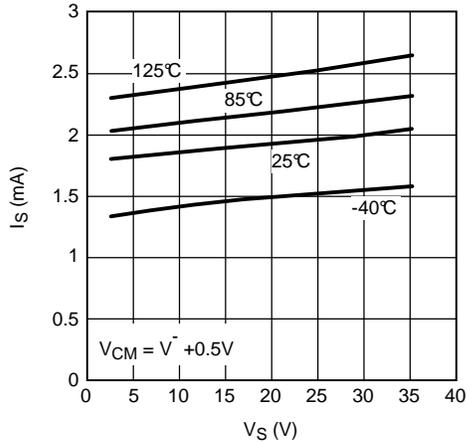


Figure 37. I_S vs. V_S (LM7322)

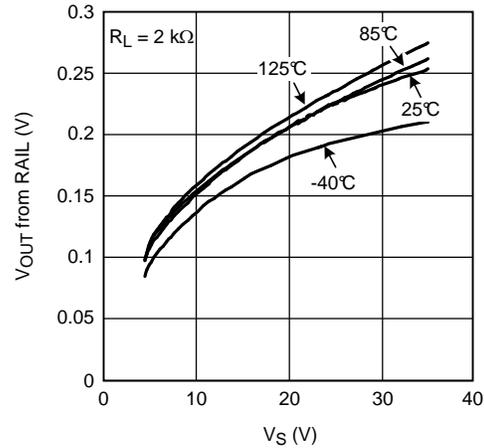


Figure 38. Positive Output Swing vs. Supply Voltage

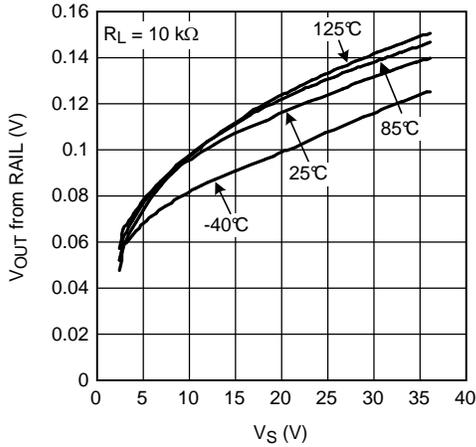


Figure 39. Positive Output Swing vs. Supply Voltage

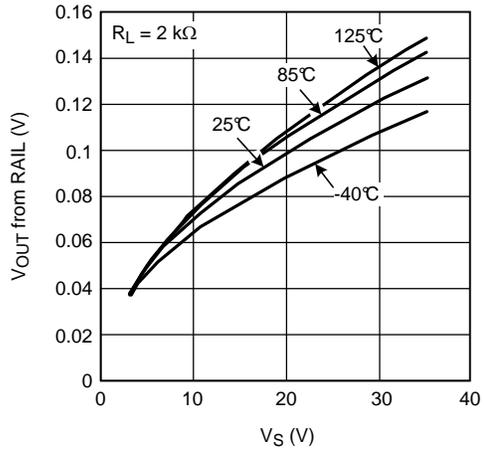


Figure 40. Negative Output Swing vs. Supply Voltage

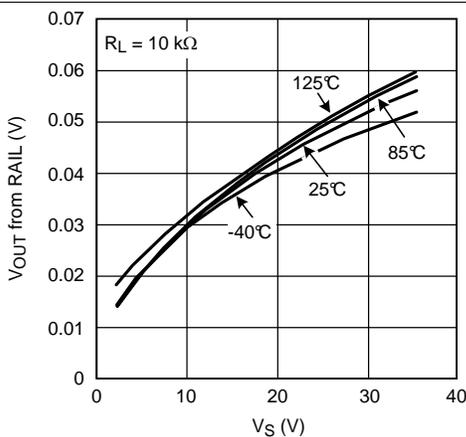


Figure 41. Negative Output Swing vs. Supply Voltage

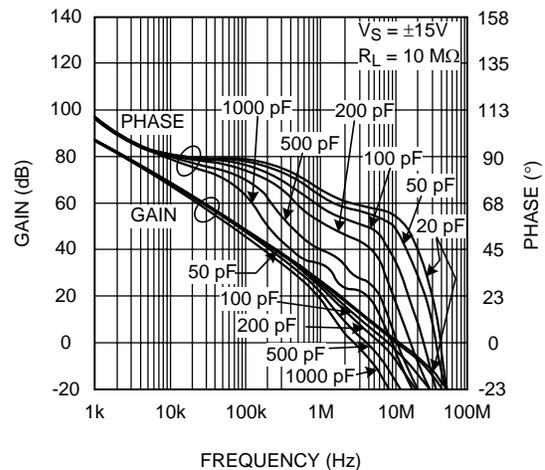


Figure 42. Open-Loop Frequency Response with Various Capacitive Load

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

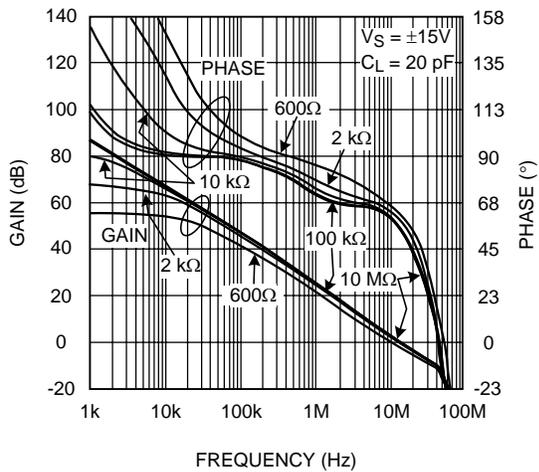


Figure 43. Open-Loop Frequency Response with Various Resistive Load

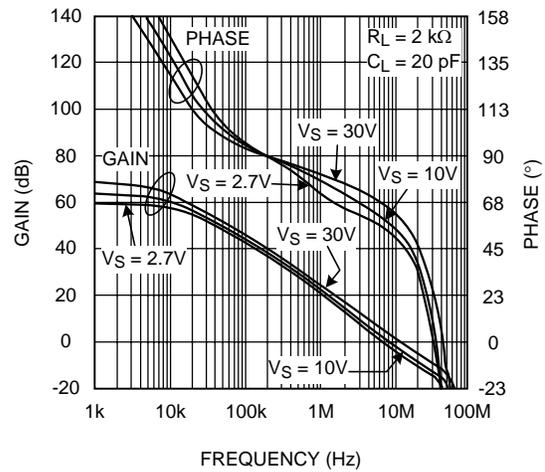


Figure 44. Open-Loop Frequency Response with Various Supply Voltage

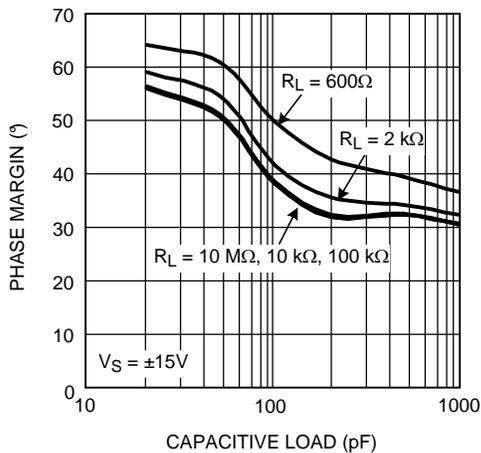


Figure 45. Phase Margin vs. Capacitive Load

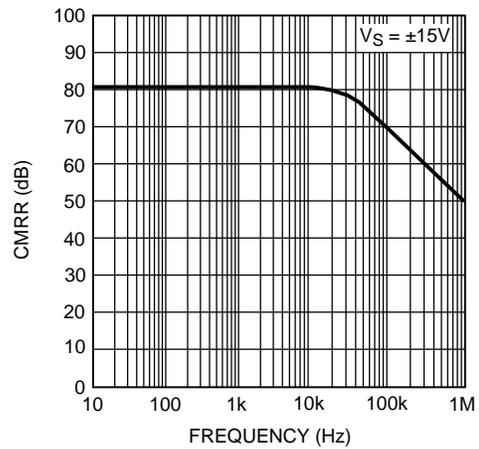


Figure 46. CMRR vs. Frequency

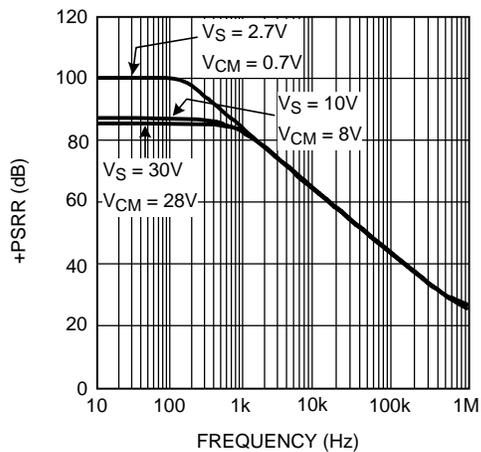


Figure 47. +PSRR vs. Frequency

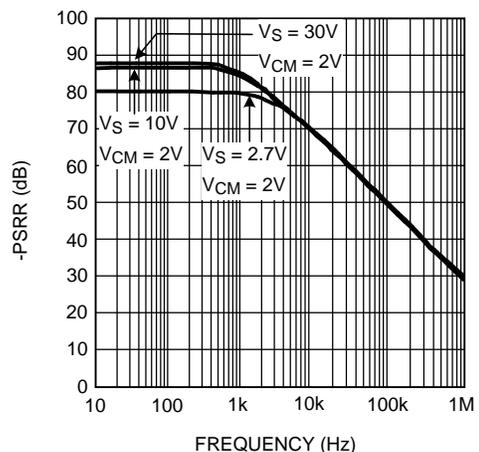


Figure 48. -PSRR vs. Frequency

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

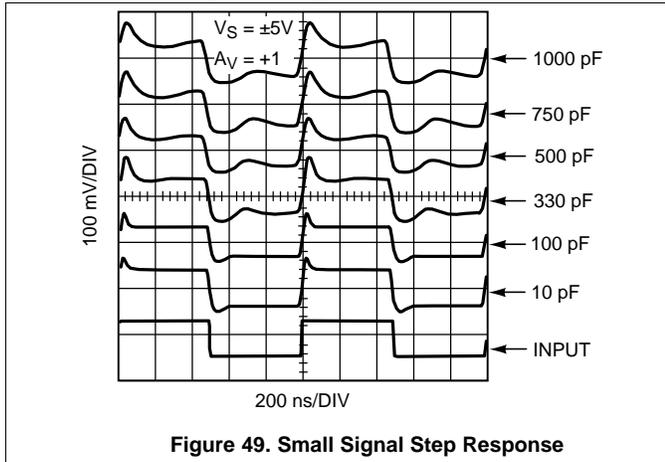


Figure 49. Small Signal Step Response

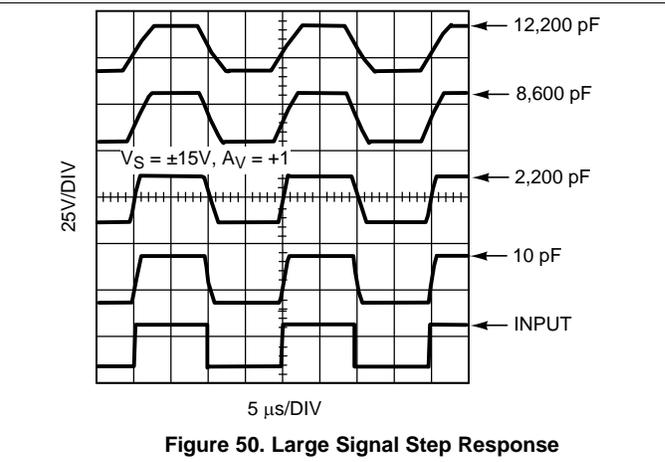


Figure 50. Large Signal Step Response

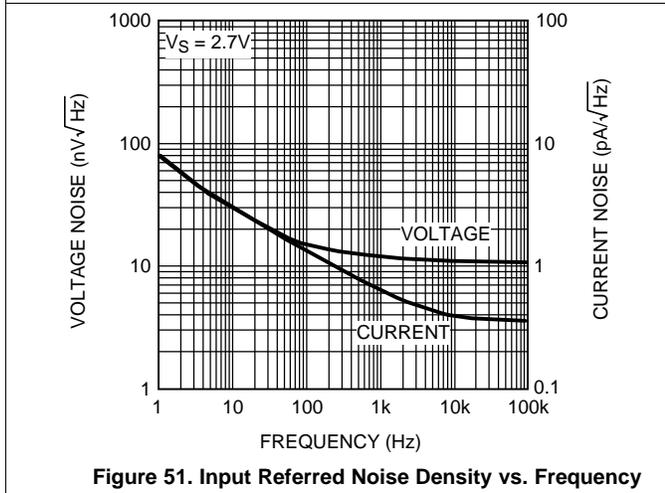


Figure 51. Input Referred Noise Density vs. Frequency

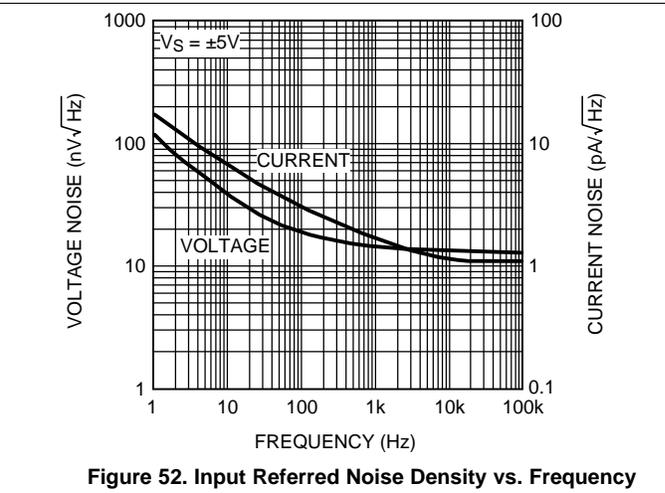


Figure 52. Input Referred Noise Density vs. Frequency

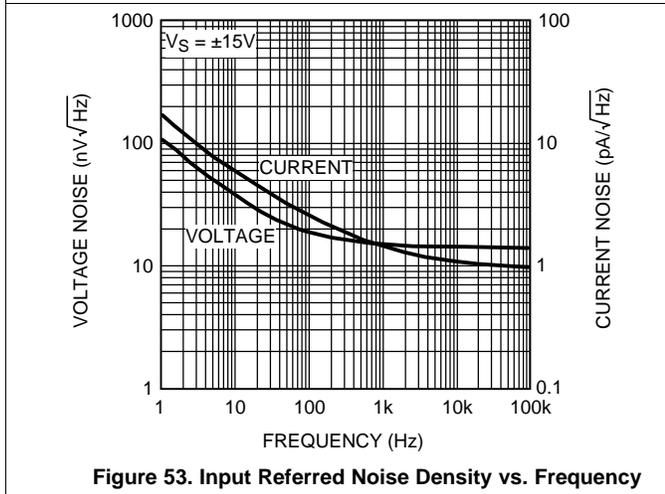


Figure 53. Input Referred Noise Density vs. Frequency

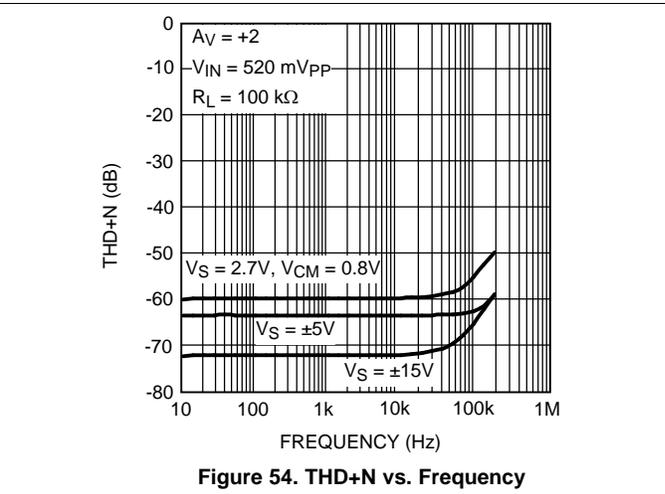


Figure 54. THD+N vs. Frequency

Typical Characteristics (continued)

Unless otherwise specified: $T_A = 25^\circ\text{C}$.

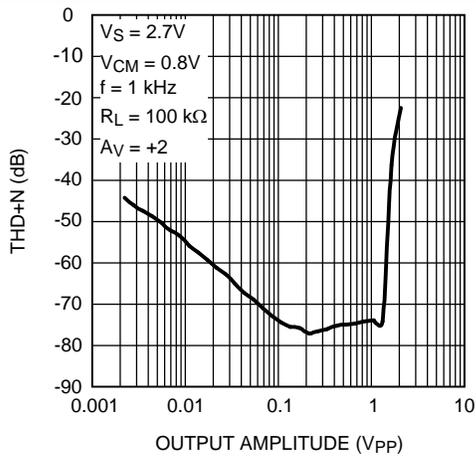


Figure 55. THD+N vs. Output Amplitude

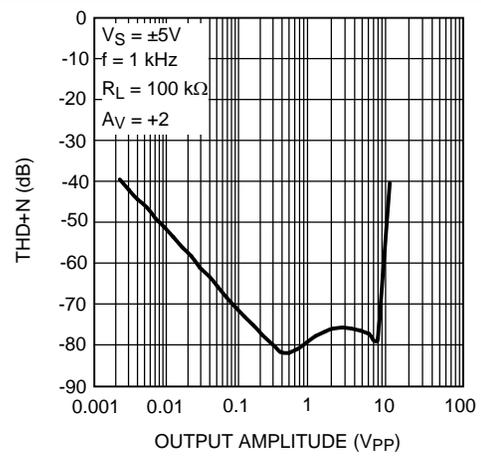


Figure 56. THD+N vs. Output Amplitude

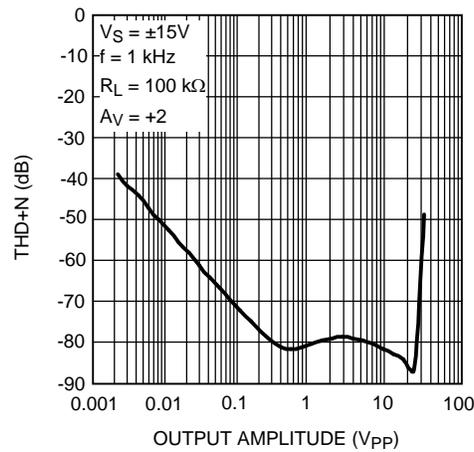


Figure 57. THD+N vs. Output Amplitude

8 Detailed Description

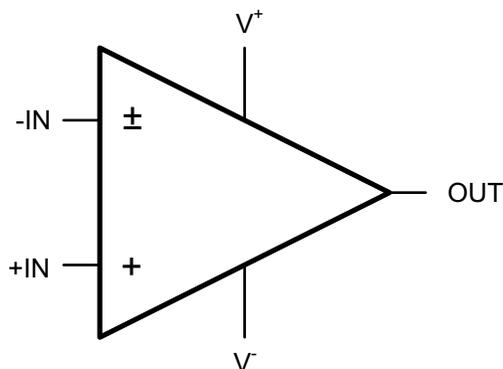
8.1 Overview

The LM732xx devices are rail-to-rail input and output amplifiers with wide operating voltages and high-output currents. The LM732xx family is efficient, achieving 18-V/ μ s slew rate and 20-MHz unity gain bandwidth while requiring only 1 mA of supply current per op amp. The LM732xx device performance is fully specified for operation at 2.7 V, ± 5 V and ± 15 V.

The LM732xx devices are designed to drive unlimited capacitive loads without oscillations. All LM7321x and LM7322x parts are tested at -40°C , 125°C , and 25°C , with modern automatic test equipment. High performance from -40°C to 125°C , detailed specifications, and extensive testing makes them suitable for industrial, automotive, and communications applications.

Greater than rail-to-rail input common-mode voltage range with 50 dB of common-mode rejection across this wide voltage range, allows both high-side and low-side sensing. Most device parameters are insensitive to power supply voltage, and this makes the parts easier to use where supply voltage may vary, such as automotive electrical systems and battery-powered equipment. These amplifiers have true rail-to-rail output and can supply a respectable amount of current (15 mA) with minimal head room from either rail (300 mV) at low distortion (0.05% THD+Noise).

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Output Short Circuit Current and Dissipation Issues

The LM732xx output stage is designed for maximum output current capability. Even though momentary output shorts to ground and either supply can be tolerated at all operating voltages, longer lasting short conditions can cause the junction temperature to rise beyond the absolute maximum rating of the device, especially at higher supply voltage conditions. Below supply voltage of 6 V, the output short circuit condition can be tolerated indefinitely.

With the op amp tied to a load, the device power dissipation consists of the quiescent power due to the supply current flow into the device, in addition to power dissipation due to the load current. The load portion of the power itself could include an average value (due to a DC load current) and an AC component. DC load current would flow if there is an output voltage offset, or the output AC average current is non-zero, or if the op amp operates in a single supply application where the output is maintained somewhere in the range of linear operation.

Therefore,

$$P_{\text{TOTAL}} = P_{\text{Q}} + P_{\text{DC}} + P_{\text{AC}} \quad (1)$$

Feature Description (continued)

The Op Amp Quiescent Power Dissipation is calculated as:

$$P_Q = I_S \times V_S$$

where

- I_S : Supply Current
 - V_S : Total Supply Voltage ($V^+ - V^-$)
- (2)

The DC Load Power is calculated as:

$$P_{DC} = I_O \times (V_r - V_o)$$

where

- V_o : Average Output Voltage
 - V_r : V^+ for sourcing and V^- for sinking current
- (3)

The AC Load Power is calculated as P_{AC} = See [Table 1](#).

[Table 1](#) shows the maximum AC component of the load power dissipated by the op amp for standard Sinusoidal, Triangular, and Square Waveforms:

Table 1. Normalized AC Power Dissipated in the Output Stage for Standard Waveforms

	$P_{AC} (W.\Omega/V^2)$		
	Sinusoidal	Triangular	Square
	50.7×10^{-3}	46.9×10^{-3}	62.5×10^{-3}

The table entries are normalized to V_S^2/R_L . To figure out the AC load current component of power dissipation, simply multiply the table entry corresponding to the output waveform by the factor V_S^2/R_L . For example, with ± 12 -V supplies, a 600- Ω load, and triangular waveform power dissipation in the output stage is calculated as:

$$P_{AC} = (46.9 \times 10^{-3}) \times (242/600) = 45.0 \text{ mW}$$
(4)

The maximum power dissipation allowed at a certain temperature is a function of maximum die junction temperature ($T_{J(MAX)}$) allowed, ambient temperature T_A , and package thermal resistance from junction to ambient, θ_{JA} .

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$
(5)

For the LM732xx, the maximum junction temperature allowed is 150°C at which no power dissipation is allowed. The power capability at 25°C is given by the following calculations:

For VSSOP package:

$$P_{D(MAX)} = \frac{150^\circ\text{C} - 25^\circ\text{C}}{235^\circ\text{C/W}} = 0.53 \text{ W}$$
(6)

For SOIC package:

$$P_{D(MAX)} = \frac{150^\circ\text{C} - 25^\circ\text{C}}{165^\circ\text{C/W}} = 0.76 \text{ W}$$
(7)

Similarly, the power capability at 125°C is given by:

For VSSOP package:

$$P_{D(MAX)} = \frac{150^\circ\text{C} - 125^\circ\text{C}}{235^\circ\text{C/W}} = 0.11 \text{ W}$$
(8)

For SOIC package:

$$P_{D(MAX)} = \frac{150^\circ\text{C} - 125^\circ\text{C}}{165^\circ\text{C/W}} = 0.15 \text{ W}$$
(9)

Figure 58 shows the power capability vs. temperature for VSSOP and SOIC packages. The area under the maximum thermal capability line is the operating area for the device. When the device works in the operating area where P_{TOTAL} is less than $P_{D(MAX)}$, the device junction temperature will remain below $150^{\circ}C$. If the intersection of ambient temperature and package power is above the maximum thermal capability line, the junction temperature will exceed $150^{\circ}C$ and this should be strictly prohibited.

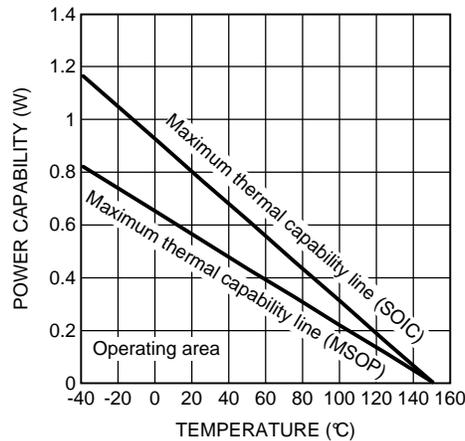


Figure 58. Power Capability vs. Temperature

When high power is required and ambient temperature can't be reduced, providing air flow is an effective approach to reduce thermal resistance therefore to improve power capability.

8.3.2 Estimating the Output Voltage Swing

It is important to keep in mind that the steady-state output current will be less than the current available when there is an input overdrive present. For steady-state conditions, the Output Voltage vs. Output Current plot (*Typical Characteristics* section) can be used to predict the output swing. Figure 59 and Figure 60 show this performance along with several load lines corresponding to loads tied between the output and ground. In each case, the intersection of the device plot at the appropriate temperature with the load line would be the typical output swing possible for that load. For example, a $1\text{-k}\Omega$ load can accommodate an output swing to within 250 mV of V^- and to 330 mV of V^+ ($V_S = \pm 15\text{ V}$) corresponding to a typical 29.3 V_{PP} unclipped swing.

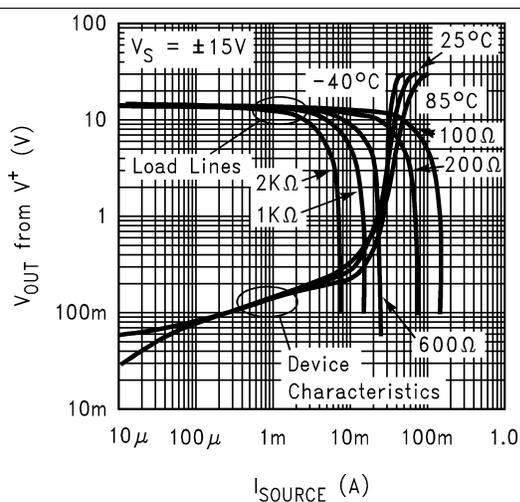


Figure 59. Output Sourcing Characteristics With Load Lines

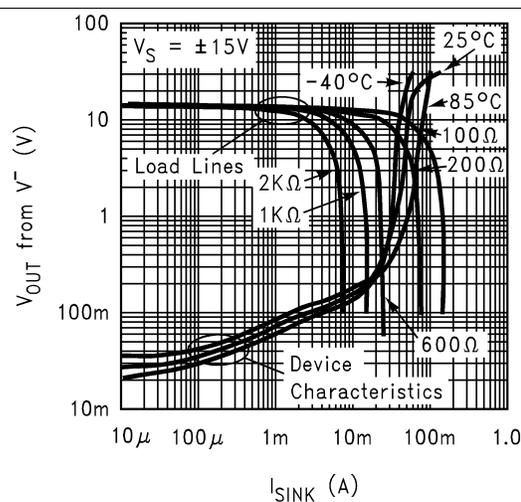


Figure 60. Output Sinking Characteristics With Load Lines

8.4 Device Functional Modes

8.4.1 Driving Capacitive Loads

The LM732xx are specifically designed to drive unlimited capacitive loads without oscillations as shown in [Figure 61](#).

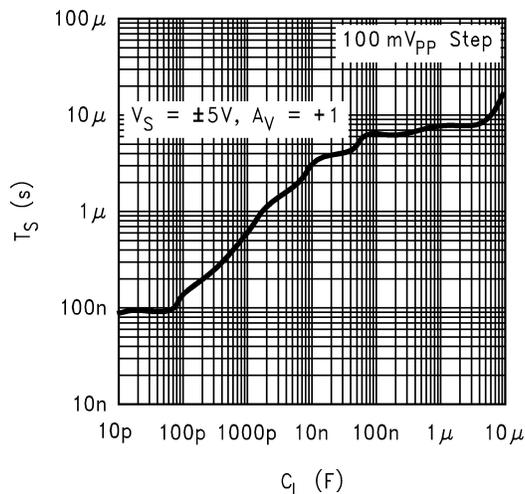


Figure 61. ±5% Settling Time vs. Capacitive Load

In addition, the output current handling capability of the device allows for good slewing characteristics even with large capacitive loads as shown in [Figure 62](#) and [Figure 63](#).

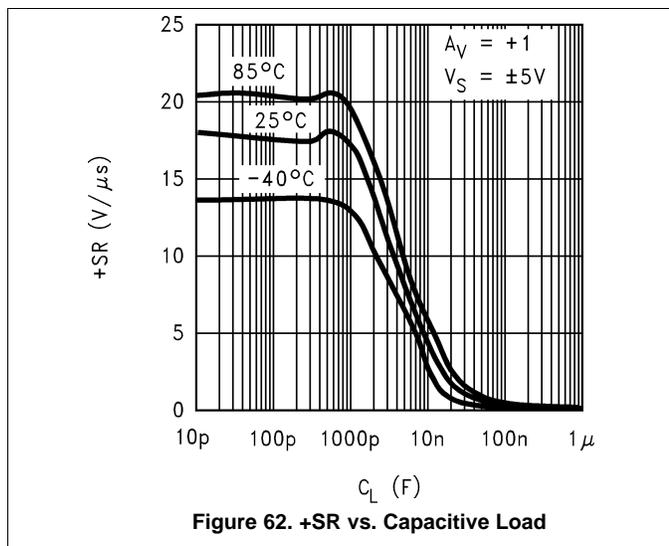


Figure 62. +SR vs. Capacitive Load

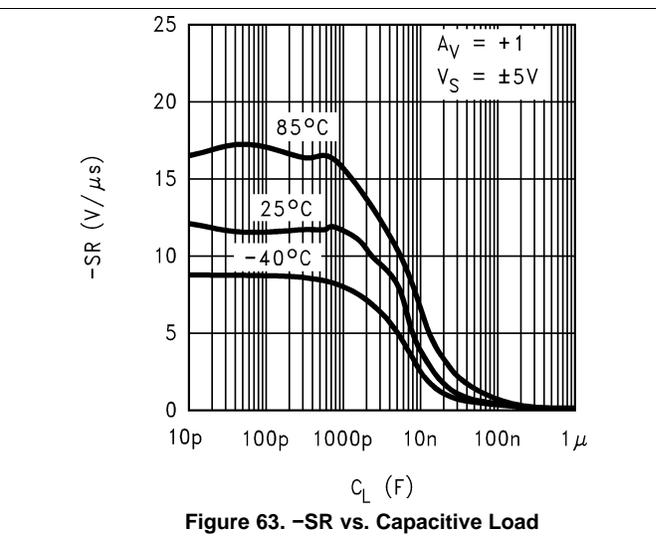


Figure 63. -SR vs. Capacitive Load

The combination of these features is ideal for applications such as TFT flat panel buffers, A/D converter input amplifiers, and so forth.

However, as in most op amps, addition of a series isolation resistor between the op amp and the capacitive load improves the settling and overshoot performance.

Output current drive is an important parameter when driving capacitive loads. This parameter will determine how fast the output voltage can change. Referring to the Slew Rate vs. Capacitive Load Plots (*Typical Characteristics* section), two distinct regions can be identified. Below about 10,000 pF, the output Slew Rate is solely determined by the compensation capacitor value of the op amp and available current into that capacitor. Beyond 10 nF, the Slew Rate is determined by the available output current of the op amp.

Device Functional Modes (continued)

NOTE

Because of the lower output sourcing current compared to the sinking one, the Slew Rate limit under heavy capacitive loading is determined by the positive transitions.

An estimate of positive and negative slew rates for loads larger than 100 nF can be made by dividing the short circuit current value by the capacitor.

For the LM732xx, the available output current increases with the input overdrive. Referring to Figure 64 and Figure 65, it can be seen that both sourcing and sinking short circuit current increase as input overdrive increases. In a closed-loop amplifier configuration, during transient conditions while the fed back output has not quite caught up with the input, there will be an overdrive imposed on the input allowing more output current than would normally be available under steady-state condition. Because of this feature, the output stage quiescent current of the op amp can be kept to a minimum, thereby reducing power consumption, while enabling the device to deliver large output current when the need arises (such as during transients).

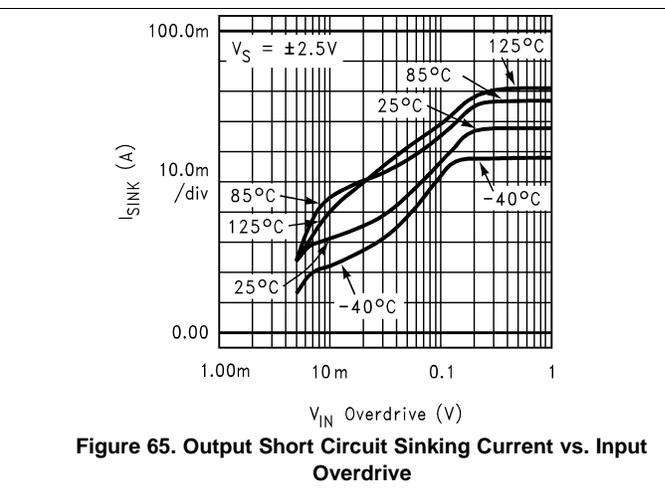
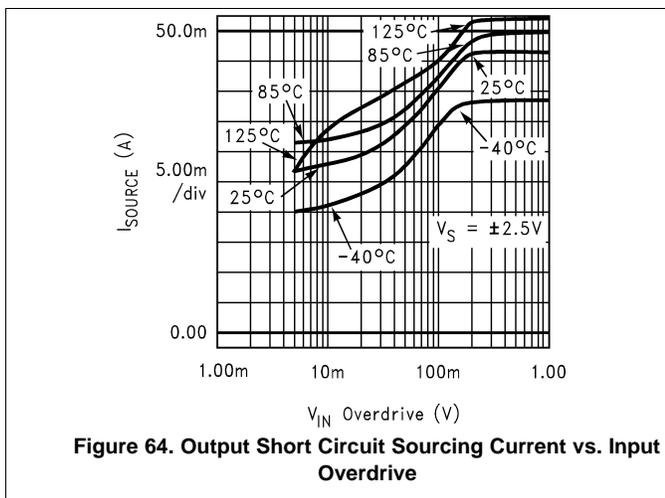
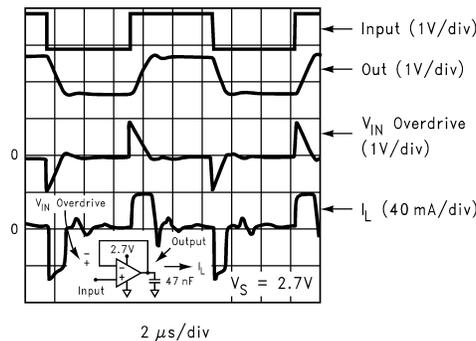


Figure 66 shows the output voltage, output current, and the resulting input overdrive with the device set for $A_V = +1$ and the input tied to a $1-V_{PP}$ step function driving a 47-nF capacitor. As can be seen, during the output transition, the input overdrive reaches 1-V peak and is more than enough to cause the output current to increase to its maximum value (see Figure 64 and Figure 65 plots).

NOTE

Because of the larger output sinking current compared to the sourcing one, the output negative transition is faster than the positive one.



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

9.1.1 Similar High-Output Devices

The LM7332 is a dual rail-to-rail amplifier with a slightly lower GBW capable of sinking and sourcing 100 mA. It is available in SOIC and VSSOP packages.

The LM4562 is dual op amp with very low noise and 0.7-mV voltage offset.

The LME49870 and LME49860 are single and dual low-noise amplifiers that can work from ± 22 -V supplies.

9.1.2 Other High Performance SOT-23 Amplifiers

The LM7341 is a 4-MHz rail-to-rail input and output part that requires only 0.6 mA to operate, and can drive unlimited capacitive load. It has a voltage gain of 97 dB, a CMRR of 93 dB, and a PSRR of 104 dB.

The LM6211 is a 20-MHz part with CMOS input, which runs on ± 12 -V or 24-V single supplies. It has rail-to-rail output and low noise.

The LM7121 has a gain bandwidth of 235 MHz.

Detailed information on these parts can be found at www.ti.com.

9.2 Typical Application

Figure 67 shows a typical application where the LM732xx is used as a buffer amplifier for the V_{COM} signal employed in a TFT LCD flat panel:

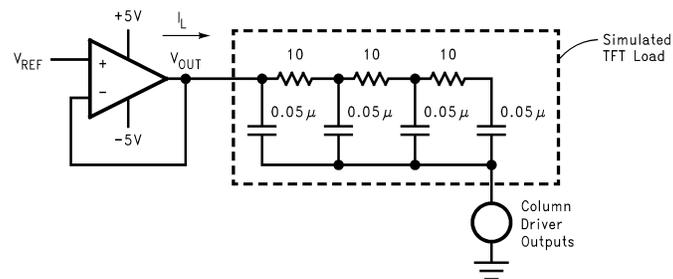


Figure 67. V_{COM} Driver Application Schematic

9.2.1 Design Requirements

For this example application, the supply voltage is +5 V, and noninverting gain is necessary.

Typical Application (continued)

9.2.2 Detailed Design Procedure

Figure 68 shows the time domain response of the amplifier when used as a V_{COM} buffer/driver with V_{REF} at ground. In this application, the op amp loop will try and maintain its output voltage based on the voltage on its noninverting input (V_{REF}) despite the current injected into the TFT simulated load. As long as this load current is within the range tolerable by the LM732xx (45-mA sourcing and 65-mA sinking for ± 5 -V supplies), the output will settle to its final value within less than 2 μ s.

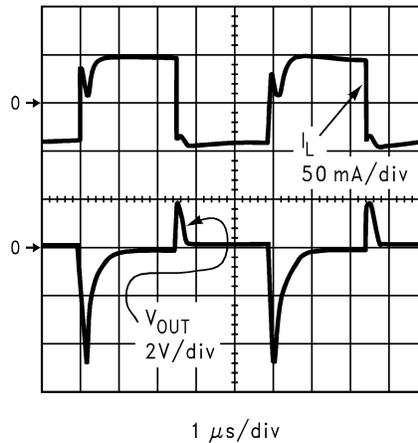


Figure 68. V_{COM} Driver Performance Scope Photo

9.2.3 Application Curve

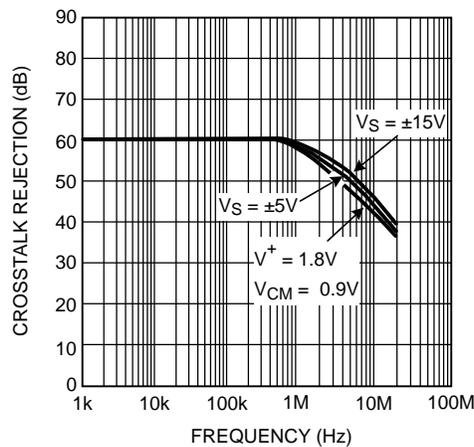


Figure 69. Crosstalk Rejection vs. Frequency

10 Power Supply Recommendations

The use of supply decoupling is mandatory in most applications. As with most relatively high-speed or high-output current op amps, best results are achieved when each supply line is decoupled with two capacitors; a small value ceramic capacitor (about 0.01 μF) placed very close to the supply lead in addition to a large value Tantalum or Aluminum ($> 4.7 \mu\text{F}$). The large capacitor can be shared by more than one device if necessary. The small ceramic capacitor maintains low supply impedance at high frequencies while the large capacitor will act as the charge *bucket* for fast load current spikes at the op amp output. The combination of these capacitors will provide supply decoupling and will help keep the op amp oscillation free under any load.

11 Layout

11.1 Layout Guidelines

Take care to minimize the loop area formed by the bypass capacitor connection between supply pins and ground. A ground plane underneath the device is recommended; any bypass components to ground should have a nearby via to the ground plane. The optimum bypass capacitor placement is closest to the corresponding supply pin. Use of thicker traces from the bypass capacitors to the corresponding supply pins will lower the power supply inductance and provide a more stable power supply.

The feedback components should be placed as close to the device as possible to minimize stray parasitics.

11.2 Layout Example

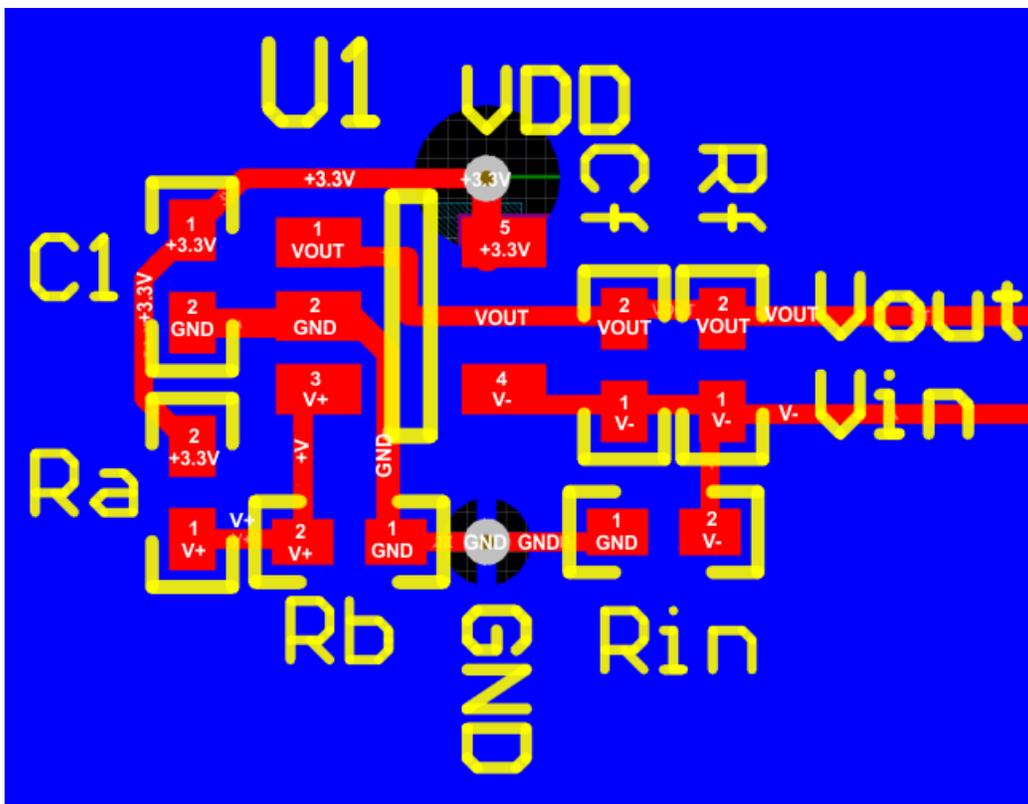


Figure 70. LM732xx Layout Example

12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LM7321	Click here				
LM7322	Click here				

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM7321MA/NOPB	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	LM732 1MA
LM7321MAX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LM732 1MA
LM7321MAX/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM732 1MA
LM7321MF/NOPB	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	AU4A
LM7321MFE/NOPB	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	AU4A
LM7321MFX/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AU4A
LM7321MFX/NOPB.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AU4A
LM7321QMF/NOPB	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	AR8A
LM7321QMFE/NOPB	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	AR8A
LM7321QMFX/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AR8A
LM7321QMFX/NOPB.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AR8A
LM7321QMFX/NOPB.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AR8A
LM7322MA/NOPB	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	LM732 2MA
LM7322MAX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LM732 2MA
LM7322MAX/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM732 2MA
LM7322MM/NOPB	Active	Production	VSSOP (DGK) 8	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AZ4A
LM7322MM/NOPB.B	Active	Production	VSSOP (DGK) 8	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	AZ4A
LM7322MME/NOPB	Obsolete	Production	VSSOP (DGK) 8	-	-	Call TI	Call TI	-40 to 125	AZ4A
LM7322QMA/NOPB	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	LM732 2QMA
LM7322QMAX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(7322Q, LM732) 2QMA
LM7322QMAX/NOPB.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(7322Q, LM732) 2QMA
LM7322QMAX/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(7322Q, LM732) 2QMA

- (1) **Status:** For more details on status, see our [product life cycle](#).
- (2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- (4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

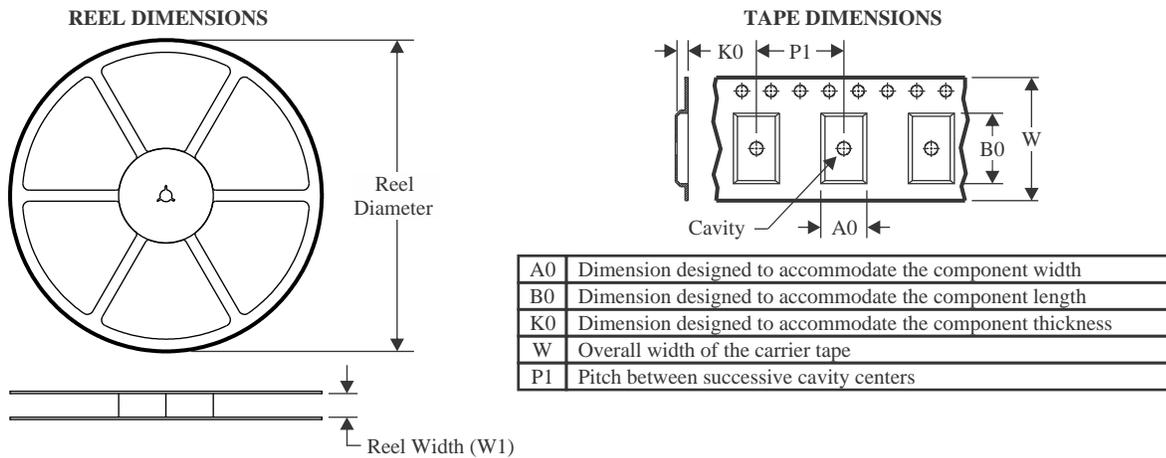
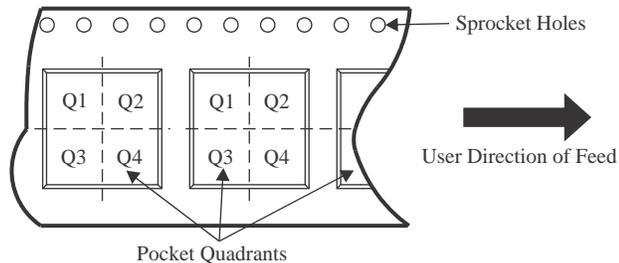
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LM7321, LM7321-Q1, LM7322, LM7322-Q1 :

- Catalog : [LM7321](#), [LM7322](#)
- Automotive : [LM7321-Q1](#), [LM7322-Q1](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM7321MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM7321MFX/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM7321QMF/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM7321QMF/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM7322MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM7322MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM7322MM/NOPB	VSSOP	DGK	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM7322MM/NOPB	VSSOP	DGK	8	1000	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
LM7322QMAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

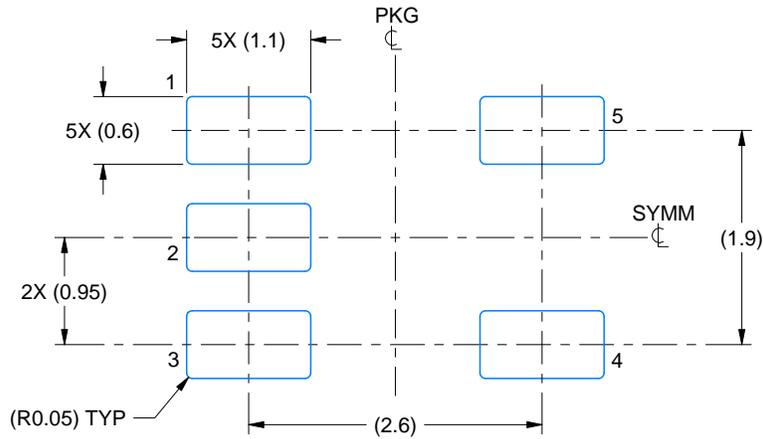
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM7321MAX/NOPB	SOIC	D	8	2500	353.0	353.0	32.0
LM7321MFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LM7321QMFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LM7321QMFX/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LM7322MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM7322MAX/NOPB	SOIC	D	8	2500	353.0	353.0	32.0
LM7322MM/NOPB	VSSOP	DGK	8	1000	208.0	191.0	35.0
LM7322MM/NOPB	VSSOP	DGK	8	1000	366.0	364.0	50.0
LM7322QMAX/NOPB	SOIC	D	8	2500	353.0	353.0	32.0

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

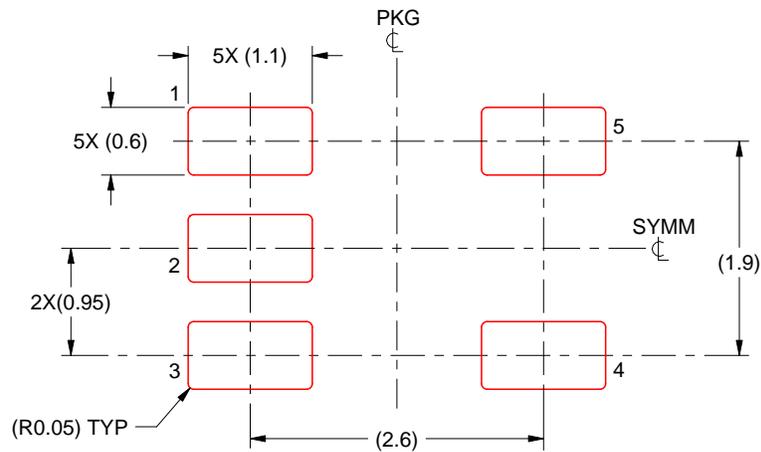
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

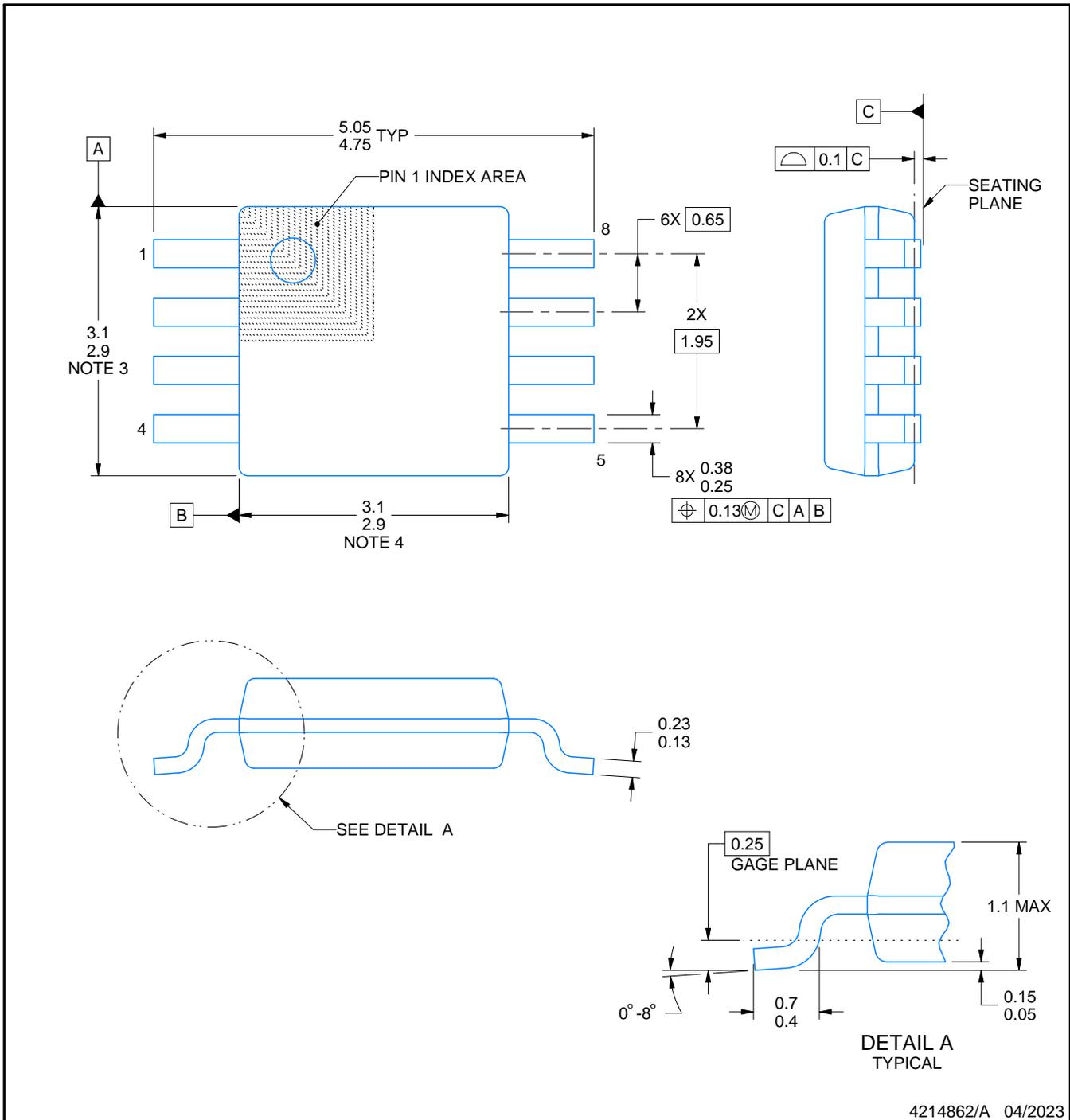
DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

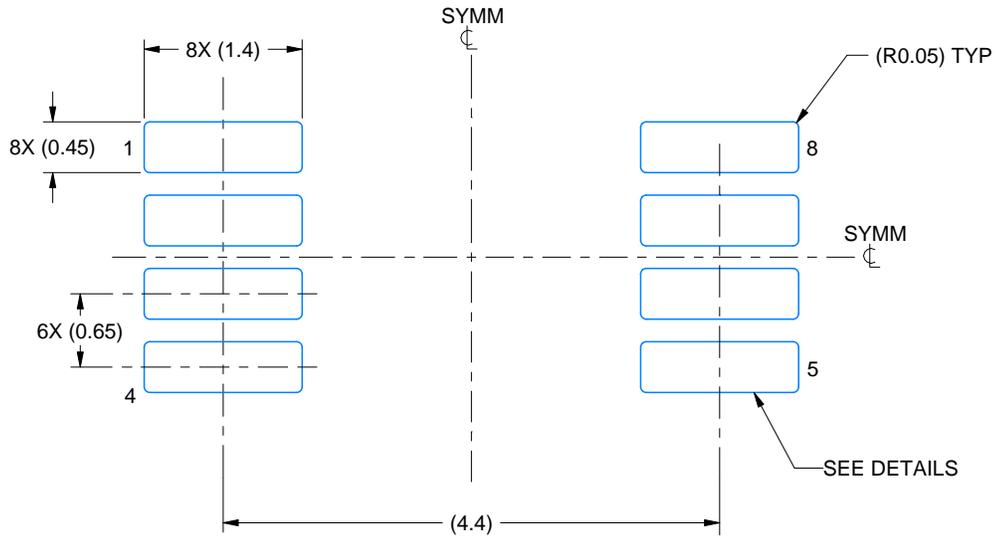
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

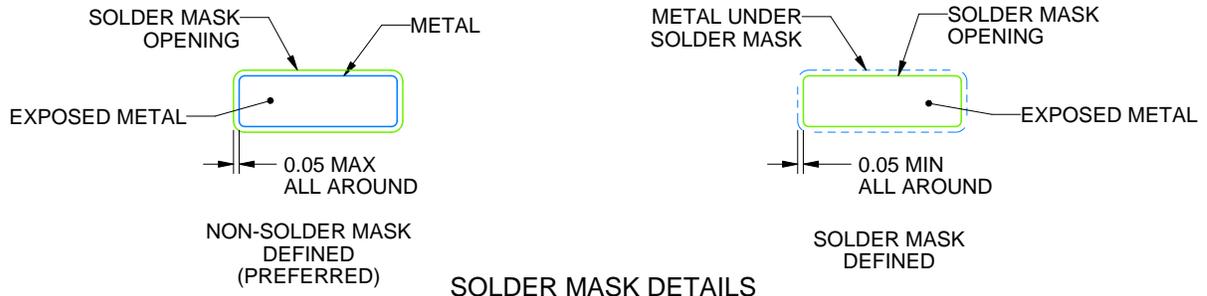
DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

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NOTES: (continued)

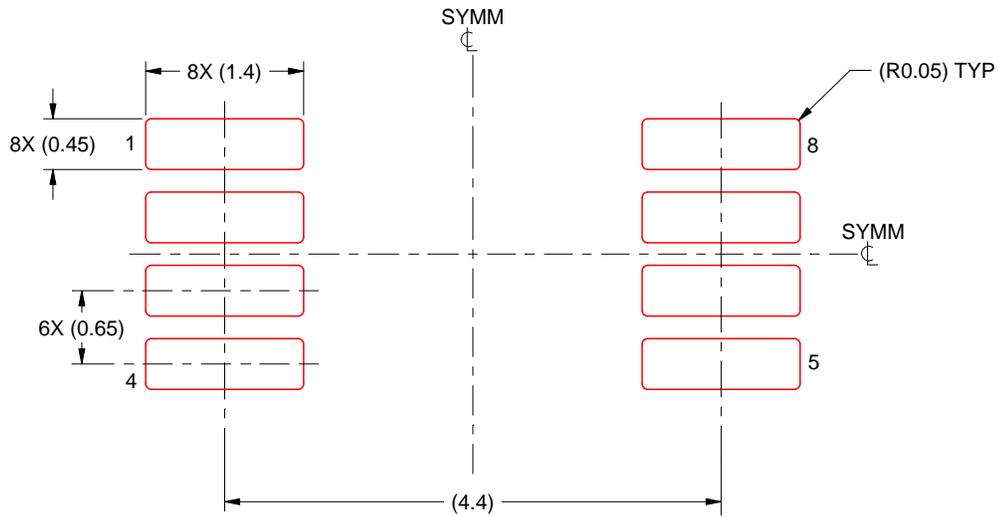
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

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NOTES: (continued)

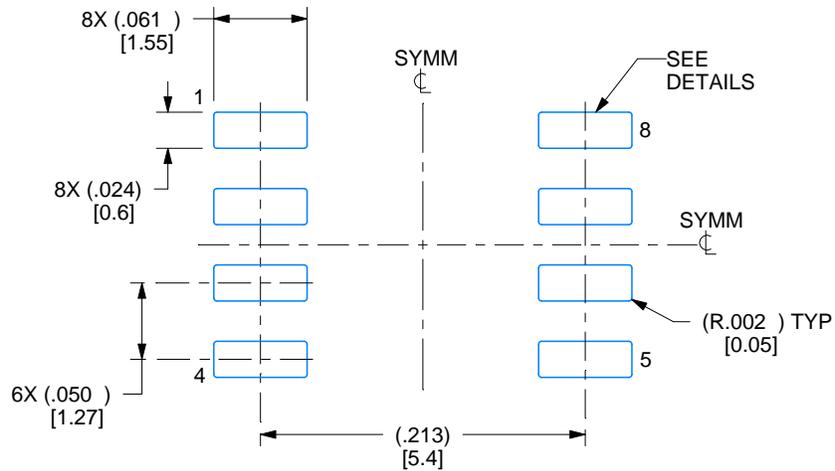
11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

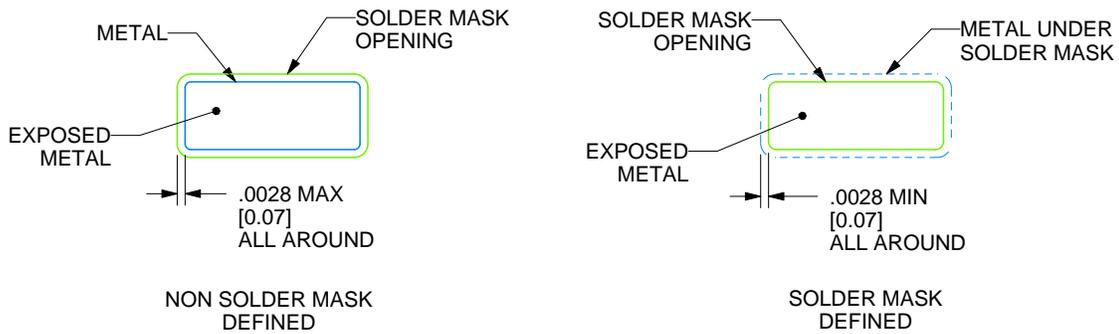
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

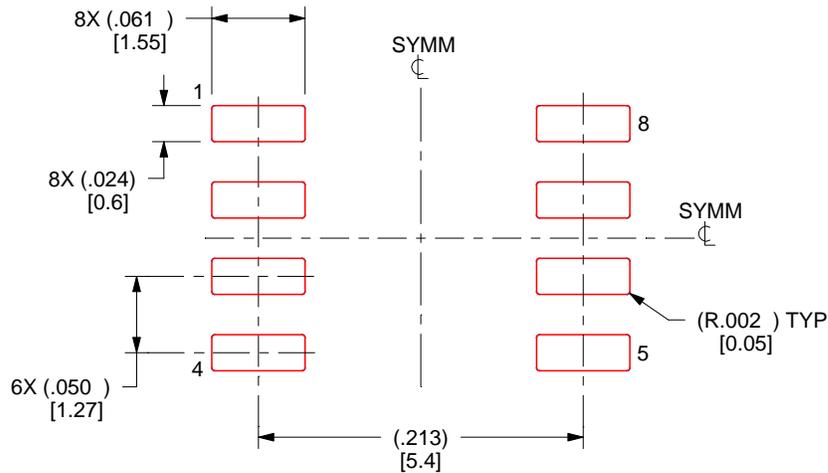
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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